INSTRUCTION MANUAL FT-625RD FT-625R

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Amateur Radio Directory

YAESU MUSEN CO, LTD.

TOKYO JAPAN.

ALL-MODE 6M MEMORY TRANSCEIVER FT-625RD, FT-625R



GENERAL

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The FT-625RD is a high performance, all solid state transceiver for the most discriminating six meter operators. Covering the entire 50-54 MHz range in four bands of 1 MHz each, the FT-625RD features digital plus analog readout of the operating frequency on all modes of operation: SSB, CW, AM, and FM, An economy version, the FT-625R, includes a 100 kHz crystal calibrator for alignment of the analog display.

Yaesu's exciting memory system, which provides storage and recall of any transmit, receive, or transceive frequency, is an available option for your FT-625RD. Also optional is a 600 Hz CW filter which may be used **in addition** to the normal 2.4 kHz bandwidth for CW.

Built into every FT-625RD are an RF speech processor, a high-performance noise blanker, VOX, semi-break-in CW with sidetone, and offset tuning (clarifier) for both receive and transceive frequencies. Also included is an automatic mic gain control (AMGC), which will act as a microphone squelch to minimize transmission of random noises in the operating room.

For FM enthusiasts, the FT-625RD includes \pm 1 MHz repeater split, and an auxiliary split may be used via an optional crystal. Tone burst and a discriminator center meter are included for maximum versatility.

A front panel control will vary the power output up to the maximum of 25 watts output. For energy conservation or nighttime mobile operation, the front panel lamps and digital display may be dimmed by pressing a front panel switch. Rear panel connections for relay control, ALC input, PTT (footswitch), CW key, and external speaker allow full interface with peripheral station equipment.

All circuits are fully solid state, and computer-type plug-in circuit boards are used for increased reliability and ease of maintenance. The FT-625RD is entirely self-contained, requiring only an antenna and power source for operation. The FT-625RD is normally supplied for 117 VAC (USA model) or 13.6 VDC operation, but the AC transformer may easily be rewired for operation from 100/110/117/200/220/234 VAC. Two power cords are supplied with the FT-625RD; selection of the power source is automatically made when the proper cord is inserted into the rear panel receptacle.

The transceiver weighs approximately 9 kg, and is 280 mm wide, 125 mm high, and 315 mm deep. Heavy-duty construction provides an extremely rugged package which is virtually immune to the effects of shock and vibration encountered in mobile service.

SPECIFICATIONS

GENERAL

Frequency range	:	50-51 MHz52-53 MHz51-52 MHz53-54 MHz		
Frequency readout	:	Digital readout to 0.1 kHz, analog display resolution better than 1 kHz.		
Modes of operation	:	USB, LSB, CW, AM, FM.		
Frequency stability	:	Within 100 Hz during any 30 minute period after warmup. Not more than 20 Hz with 10% line voltage variation.		
Intermediate frequencies	:	First IF = 10.81 MHz Second IF = 455 kHz (AM/FM only)		
Antenna impedance	:	50 ohms unbalanced		
Repeater split	:	1 MHz installed, any split up to 4 MHz possible using optional crystal.		
Power requirements	:	AC 100/110/117/200/220/234 Volts, 50/60 Hz DC 13.8 Volts, negative ground		
Power consumption	:	AC Receive 35 VA Transmit 135 VA DC Receive 0.7 A Transmit 7.0 A 50% duty cycle		
Size	:	280(W) x 125(H) x 300(D) mm.		
Weight	:	Approximately 9 kg.		
RECEIVER				
Sensitivity	:	SSB/CW 0.5 μV for S/N 20 dB AM 0.5 μV for S/N 10 dB (400 Hz 30% mod.) FM 0.35 μV for 20 dB QS		
Selectivity		SSB/CW-W : 2.4 kHz @ -6 dB, 4.1 kHz @ -60 dB *** CW-N : 600 Hz @ -6 dB, 1.6 kHz @ -60 dB AM : 4 kHz @ -6 dB, 15 kHz @ -60 dB FM : 15 kHz @ -6 dB, 32 kHz @ -60 dB *** With optional CW filter installed.		
Image response	:	Better than -60 dB.		
Spurious response	:	Better than 1 μ V at antenna input.		
Audio output impedance	:	4 ohms nominal.		
Audio output	:	2 watts @ 10% THD.		

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TRANSMITTER

Audio response	: 300–2700 Hz, –6	dB
Carrier suppression	: -40 dB or better.	
Unwanted sideband suppressi	n: -40 dB or better.	
Spurious radiation	: -60 dB or better.	
FM deviation	: Factory set at ± 5	kHz.
Power output		watts watts
		walls

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SEMICONDUCTOR COMPLEMENT

Integrated Circuits	:			Field Effect Transi	stors:		
F4011	1	TA7060P	1	2 SK 19GR	9	3SK51	2
MC1496G	2	TA7063P	1	2SK30AY	2	3SK59Y	11
MC14011B	5	TC5032P	1	3SK40M	3		
MC14069B	1	μPC577H	1				
MSM561	1	μPC1037H	1	Transistors:			
MSM5564	1	μPC14305	1	2 SA 496	1	2SC735Y	1
MSM5576	1	μPC14308	1	2SA564AR	2	2SC784R	2
SN75453	3	μPC14308S	1	2SA695D	1	2SC784BN	1
SN76514N	1			2SB529	1	2SC1815Y	41
				2SC372Y	14	2SC1945D	1
Germanium Diode	s:			2SC373	6	2SC2053	1
1S188FM	15	1S1007(GB)	16	2SC496	7	2SC2099	2
				2SC4960	1	2SD313	1
Silicon Diodes:				2SC710	2	2SD359	1
1\$1209	1	MC301	4	2SC711D	1	MJ802	1
181209	59	U05B	1	2 S C730	1	MPS-A13	1
10D1	18	S15VB10	1				
TOD I	10	515 010	1	Zener Diodes:			
Silicon Varistors:				WZ034	1	WZ090	1
MV-103	5	MV-5W	1				
				Light Emitting Dio	des:		
Varactor Diodes:				GD4-203SRD	11		
1\$2209	16						
				LED Display			
				5082-7740	6		

Specifications subject to change without notice.

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CONTROLS AND SWITCHES

This transceiver has been specifically designed for ease of operation and versatility. All internal controls have been carefully preset at the factory. The operator may, however, be unfamiliar with operation of some of the controls, and improper adjustment thereof may result in poor transceiver performance. The various front panel controls and switches are described in the following section, and the operator should become familiar with the function of every control before attempting transceiver operation.



(1) MODE SWITCH

This switch chooses the mode of operation: LSB, USB, CW-W (SSB bandwidth). CW-N (using optional 600 Hz CW filter), AM, and FM.

(2) CLARIFIER

The clarifier allows offsetting of the transceive or receive frequency ± 4 kHz from the operating frequency established by the main tuning dial.

(3) MAIN TUNING DIAL

The main tuning control is a dual rate, doubleshaft mechanism which provides for both fast and slow tuning rates. The main dial skirt is calibrated in 1 kHz increments, and the analog dial window is calibrated in 100 kHz increments. Determination of the 1 MHz band segment is made by the BAND switch.

(4) BAND SWITCH

The BAND switch selects one of the four 1 MHz segments of the six-meter band.

(5) SELECT SWITCH

This switch selects frequency control between the VFO/FIX mode and memory (optional) control of the transmit, receive, or transceive frequency.

(6) MEMORY

When the optional memory unit is installed, a new frequency may be stored in memory by pressing the MEMORY switch.

(7) CHANNEL

This switch selects between VFO control or one of the 5 crystal controlled positions available per band.

(8) DIM

This switch, when pressed, dims the front panel lamps and digital display for reduced power consumption or nighttime mobile operation. In the analog FT-625R, this is the MARK switch, which actuates the 100 kHz crystal calibrator.

(9) NB

This switch, when pressed, activates the noise blanker for elimination of pulse-type noise.

(10) AF GAIN

The AF GAIN control adjusts the audio output to the speaker and headphones. Clockwise rotation increases the audio output level.

(11) RF GAIN

The RF GAIN control varies the gain of the receiver RF and IF amplifiers. Maximum sensitivity is obtained when the control is set to the fully clockwise position.

(12) AMGC

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The Automatic Mic Gain Control acts as a "microphone squelch" to prevent output from the microphone amplifier stage unless a preset level of input from the microphone is present. Thus, minor noises can exist in the operating room without their going on the air.

(13) **TUNE**

The TUNE control peaks all transceiver circuits for the frequency being used.

(14) SQUELCH

This control adjusts the FM receiver squelch threshold level.

(15) PROC

This switch activates the RF speech processor.

(16) MIC GAIN

This control varies the output from the microphone amplifier stage for AM and SSB operation, and it has suffucient range to permit the use of any quality dynamic microphone having an impedance of 500 to 600 ohms.

(17) PWR CONTROL

This control is used to vary the output from the transmitter.

(18) DIAL AND DISPLAY

Frequency readout is by means of the digital and analog displays. The digital display reads out all digits of the operating frequency, with resolution to 100 Hz. The analog sub-dial is calibrated every 100 kHz, and the BAND switch and main dial skirt are used to establish the precise operating frequency.

(19) METER

The meter reads out signal strength or FM discriminator center current on receive, and relative power output on transmit.

(20) VOX GAIN

The VOX GAIN control selects between PTT and MOX (manual transmit)operation, as well as setting the VOX sensitivity.

(21) AM CARRIER

This control sets the AM carrier level.

(22) SWITCHES

RPT NOR/REV

This switch is used for operation on non-standard repeaters. In the NOR position, the transmit frequency is shifted 1 MHz lower. In the REV position, the receive frequency is shifted 1 MHz lower.

AUX/1 MHz

This switch selects the normal 1 MHz repeater split or an auxiliary split established by means of an optional crystal.

DISC/S METER

This switch selects between meter indication of discriminator center current or signal strength on receive.

AGC F/S

This switch selects between fast or slow AGC response.

CLARIFIER

The CLARIFIER switch selects between transceive (TX RX) or receive (RX) frequency offset using the clarifier control. In the center (horizontal) position, the clarifier is turned off.

(23) POWER

This is the main ON/OFF switch for both AC and DC operation.

(24) PHONES

This is a miniature phone jack for use of headphones or a speaker. The internal speaker is disabled when a plug is inserted into this jack.

(25) MIC

This is a four-conductor jack for microphone and PTT connections.

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REAR PANEL CONNECTIONS



REAR PANEL CONNECTIONS

(1) ANT

UHF female coaxial connector for antenna input.

(2) GND

Ground connection.

(3) ALC

ALC (automatic level control) input from linear amplifier, etc.

(4) RELAY CONNECTIONS: COM, MAKE, BREAK

These are relay connections for control of station equipment.

(5) SP

External speaker audio output. Audio output impedance is 4 ohms.

(6) PTT

This is used for activating the transceiver push-totalk circuitry, should the operator be using a footswitch, etc. This jack is in parallel with the mic jack PTT connection as well as the TONE IN PTT connection.

(7) KEY Key jack for CW operation.

(8) TONE IN

This is a tone pad input jack. Refer to the drawing for tone input, speaker, PTT, and DC connections.

(9) FUSE

Fuse holder. For AC operation, a 3 amp fuse is used on 100/110/117 volts, and a 2 amp fuse is used for 200/220/234 volt operation. For DC operation, a 10 amp fuse is located in the DC power cord. When replacing fuses, be certain to replace the blown fuse with one of the proper rating. WARRANTY DOES NOT COVER DAMAGE CAUSE BY IMPROPER FUSE RE-PLACEMENT.

(10) POWER

Both AC and DC cables are connected to this receptacle. They are both supplied with the transceiver.

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Microphone Connector





Headphone Plug





Phono Plug





Speaker Plug



Tone In Plug

GENERAL

The FT-625RD has been designed primarily for base station service, requiring only an antenna and power source. However, the transceiver provides for efficient mobile operation. The FT-625RD has been factory pre-tuned, and requires no alignment for operation into a 50 ohm load.

The antenna and its location are of critical importance in both fixed and mobile operation. In many cases, communications effectiveness is directly related to antenna height. The antenna should be as high and in the clear as possible, and a minimum separation of 5 feet should be maintained between VHF and other antennas. In mobile operation, it is desirable to locate the antenna as far away from the engine as possible, so as to minimize noise pickup from the ignition system.

For base station operation, the most popular antennas for DX work are the various multielement Yagi arrays, used singly or in stacked systems. Most DX work is done using horizontal polarization, while mobile antennas invariably are vertical. If much work is done with FM and/or mobile stations, some sort of vertical antenna should be used to avoid cross-polarization loss of signal.

To minimize loss in the antenna system, do not economize on coaxial cable, and use the shortest length of cable which is practicable, avoiding sharp angles or kinks. Type RG8A/U is suitable for line lengths exceeding 25 feet, while type RG58A/U may be used for mobile installations. For extremely long runs, type RG-17A/U, air-dielectric "heliax", or aluminum-jacketed foam-dielectric coax may be required. If you are using an amplifier with this transceiver, check the coaxial cable manufacturer's specifications to make sure that it is capable of handling your power level.

BASE STATION INSTALLATION

The FT-625RD is designed for use in many parts of the world, where the AC supply voltage may differ from the operator's local supply voltage. Therefore, before connecting the AC cord to the power outlet, be absolutely certain that the voltage marked on the rear of the transceiver agrees with the local AC supply voltage. If not, please refer to the transformer primary winding chart for the proper connections.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IMPROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER. OUR WARRANTY DOES NOT COVER THE DAMAGE CAUSED BY APPLICATION OF IMPROPER SUPPLY VOLTAGE.

Be sure that a proper fuse is used for the local supply voltage. For 100/110/117 volts, use a 3 amp fuse, and for 200/220/234 volts, use a 2 amp fuse.



POWER TRANSFORMER PRIMARY CONNECTIONS

CAUTION

IMPROPER FUSE REPLACEMENT CAN CAUSE PERMANENT DAMAGE IN THE EVENT OF UNUSUAL OPERATING CONDITIONS. OUR WARRANTY DOES NOT COVER DAMAGE CAUSED BY IMPROPER FUSE REPLACEMENT.

The transceiver should be connected to a good ground through a heavy braided cable. The ground lead should be connected to the terminal marked GND on the rear panel.

It is recommended that excessively warm locations be avoided. The transceiver should be situated so that adequate air circulation through cabinet openings is possible.

MOBILE INSTALLATION

The transceiver will operate satisfactorily from any 12 volt negative ground battery source by connecting the DC power cord to the rear panel receptacle. In the car, a location should be selected that is clear of heater ducts to protect it from excessive heat. No special mounting precautions need to be observed if adequate ventilation is available. A minimum of two inches of air space is recommended to allow proper air flow around the transceiver. You may put it on the seat but be sure there is clearance between the cabinet bottom and the seat. Since the transceiver requires an average of 7| A on transmit, the fuse in the DC power cable should be rated for 10 amps.

When making connections to the car battery, be certain that the RED lead is connected to the positive (+) terminal and the BLACK lead is connected to the negative (-) terminal of the battery. Reversed connections could permanently damage the transceiver. The power cable should be as short as possible, and should be connected to the battery so as to take advantage of the filtering action of the battery.

Prior to operating the transceiver in a mobile installation, the voltage regulator setting should be checked. In many vehicles, the voltage regulation is very poor, and in some cases the regulator may be set for an excessively high charging voltage. As the battery and regulator age, the maximum voltage while charging can increase to a very high level. This is not only detrimental to the battery, but it may damage the transceiver. The transceiver is designed to operate from a source voltage of 11-16.5 volts. It is desirable to set the regulator so that the highest charging voltage does not exceed 14 volts, so as to give a margin of safety. The transceiver should be switched OFF when the vehicle is started so as to prevent voltage transients from damaging the transistors.

It is recommended that the microphone furnished with this transceiver be used; however, any quality microphone of 500-600 ohm impedance may be used. Refer to Fig. 2 for the microphone plug wiring connections. The microphone bracket may be put on the side of the cabinet, or at any other convenient place by drilling two 2.5 mm holes spaced 13 mm.

A speaker is built into the transceiver. However, audio output is also available for use with an external speaker. Any speaker having an impedance of 4 ohms may be used. When an external speaker plug is inserted in the EXT SP jack on the rear panel, the internal speaker is disabled.

OPERATION

The tuning procedure for this transceiver is not complicated. However, care should be exercised in operation to secure peak performance. The following paragraphs describe the procedure for receiver and transmitter tuning.

INITIAL CHECK

Before connecting the transceiver to a power source, carefully examine the unit for any visible damage. Be sure that all modules and crystals are firmly in place, and that all controls and switches are operating normally. Be certain that the voltage specification marked on the rear panel matches the supply voltage.

FREQUENCY READOUT

The digital display indicates all digits of the operating frequency, with resolution to 0.1 kHz.

The analog display consists of three components: the bandswitch, the analog dial window, and the main tuning dial skirt. For example, let us say that it is desired to operate on 50.150 MHz. The bandswitch should be rotated to the "50" position; the main dial should then be rotated so that the dial window reads half way between "100" and "200", and so that the dial skirt indicates "50". By changing the position of the bandswitch, this positioning of the main dial will also yield 51.150, 52.150, and 53.150 MHz.



RECEIVER

After the transceiver is properly set up for operation, preset the controls and switches as follows:

POWER	Down to OFF position
MODE	Desired mode
BAND	Desired band segment.
RPT	Lever horizontal to OFF
	position
AUX/1 MHz	Lever position horizontal
	to 1 MHz
DISC	Lever position horizontal
	to S METER
CLAR	Lever position horizontal
	to OFF
MAIN TUNING DIAL .	Desired operating fre-
	quency
VOX GAIN	PTT
AF GAIN	12 o'clock position
RE GAIN	.Fully clockwise
SELECT	
CHANNEL	VFO
SQUELCH	Fully counter-clockwise
PROC	OFF (Not pushed)
AMGC	OFF (Not pushed)
NB	.OFF (Not pushed)
MIC GAIN	
AM CARRIER	Fully counter-clockwise

Reconfirm that the voltage specification on the back panel of the transceiver matches your local supply voltage. Connect the appropriate power cord to the power source, and connect an antenna to the antenna receptacle on the rear panel.

Turn on the POWER switch. The dial and meter lamps and the digital display should be illuminated. The transceiver is now ready to operate. Peak the TUNE control for maximum receiver backgrund noise; this will also peak the transmitter circuits for maximum power output.

(1) SSB and AM Modes

Using the main tuning dial, tune in an SSB signal. Upper sideband (USB) is almost universally accepted for 6 meter operation, but if a station cannot be tuned in, try switching to LSB. The AF GAIN control should be adjusted for a comfortable listening level, and the RF GAIN should, usually, be set to the fully clockwise position. If, however, the incoming signal is very strong, or if you are trying to copy a weak station adjacent to a strong one, reducing the RF GAIN somewhat may improve reception. When pulse-type noise is encoutered, such as that from an automobile ignition system, press the NB (noise balanker) switch. For AM, tune for a natural sounding voice.

(2) CW Mode

With the CLARIFIER in the OFF position, tune in a CW signal. When the incoming signal is tuned to a beat note of 800 Hz, your transmit frequency will coincide with that of the other station. When the optional 600 Hz CW filter is installed, selection of wide or narrow bandwidths may be made by placing the MODE swtich in the CW-W or CW-N position, respectively.

(3) FM Mode

Using the main tuning dial, tune in an FM signal for maximum and steady S-meter reading and a clear, natural voice output from the speaker. For accurate tuning, set the meter switch to the DISC position, and carefully adjust the tuning control until the pointer is vertical (zero on the discriminator scale).

If the S-meter wobbles, or if it is impossible to obtain clean audio, it is possible that the incoming signal is on another mode, such as SSB.

FREQUENCY CALIBRATION

(1) FT-625RD (Digital plus Analog Model)

The digital display is automatically calibrated, and no further adjustment is needed. The analog dial skirt should be rotated so that it coincides with the frequency shown on the digital display.

(2) FT-625R (Analog Model)

A. SSB/CW Modes

Activate the MARK switch, rotate the main tuning dial to the nearest 100 kHz point, and tune in the marker signal for a zero beat (lowest pitch frequency). Though it is very difficult to hear the zero point, some fine adjustment and careful listening will yield the zero beat. Rotate the dial skirt to align the "0" calibration with the vertical calibration marking. The transceiver must be recalibrated when changing modes, USB/CW to LSB.

B. AM Mode

Activate the MARK switch, and rotate the main tuning dial to the nearest 100 kHz point. Tune in the marker signal for a maximum S-meter reading. Rotate the dial skirt to align the "0" calibration with the vertical calibration marking.

C. FM Mode

Place the meter switch in the DISC position. Activate the MARK switch, and rotate the main tuning dial to the nearest 100 kHz point. Tune in the marker signal for a vertical indication of the meter pointer (zero on the discriminator center meter). Rotate the dial skirt for calibration at the "0" point, as in previous sections.

NOTE: WHEN THE MARKER SWITCH IS ACTIVATED, THE ANTENNA IS AUTOMATICALLY DISCONNECTED FOR EASIER CALIBRATION. THE LAMPS WILL ALSO BE DIMMED DURING CALIBRATION; THIS IS ENTIRELY NORMAL.

TRANSMITTER

Connect a 50 ohm dummy load or matched antenna to the coax fitting on the rear panel. If the TUNE control has been adjusted for maximum receiver noise, no further adjustment is needed for full transmitter output. The adjustment of the TUNE control for maximum output is very broad.

For adjustment of the power output level, the PWR CONTROL may be rotated as required. While this control is normally set fully clockwise, this control allows the operator to control the transmitter output level as needed.

(1) SSB Mode

The MIC GAIN control should be adjusted while speaking in a normal voice a long syllable such as the word "four". The SSB MIC GAIN should only be advanced to the point where the power output does not increase further. Excessive advancement of the gain control will result in splatter and distortion, thus reducing intelligibility. The microphone PTT switch may be used, or the VOX circuitry may be utilized (see part (5) of this section).

(2) AM Mode

Place the MODE switch in the AM position, and press the microphone PTT switch. Advance the AM CARRIER control until a reading of 7 on the meter PO scale is attained. Speaking in a normal voice, advance the MIC GAIN control unitl a slight movement of the PO needle is noted on voice peaks.

(3) CW Mode

Plug a key into the KEY jack on the rear panel. In the key-down condition, the meter will indicate between 6 and 8 on the PO scale, at full transmitter output. For semi-break-in operation, advance the VOX GAIN control until the sidetone oscillator activates the VOX relay when the key is closed. For PTT operation, rotate the VOX GAIN control to the PTT position. Keying is accomplished by closing a DC 8 V line to ground. Key down current is approximately 8 mA. Use caution when using an electronic keyer so as to avoid damage caused by reversed polarity.

(4) FM Mode

Push the microphone PTT switch while speaking into the microphone in a normal voice. All gain controls are set automatically for FM operation. The relative output meter should read between 6 and 8 at full output.

(5) VOX (Voice Controlled) Operation

Adjust the VOX GAIN control on the front panel until your voice activates the transmitter while you are speaking into the microphone in a normal voice. Set the antitrip control, VR_{402} , which is located on the AF AMP UNIT, to the minimum point that prevents speaker output from tripping the VOX. Do not use more VOX GAIN nor antitrip than necessary. Adjust the DELAY control VR_{401} for the desired VOX release time. The DELAY control is also located on the AF AMP UNIT.

(6) PTT Operation

Push-to-talk operation is accomplished by rotating the VOX GAIN control to the PTT position (but not into the click-stop, which is the MOX position). The PTT circuit may then be activated either by the microphone PTT switch or by a footswitch. If a footswitch is used, it may be connected through the rear panel PTT jack.

MEMORY OPERATION (With optional MEMORY UNIT installed)

The memory circuitry can be used to store any frequency within a 1 MHz band segment for recall and control of the transceive, receive, or transmit frequency. A frequency is memorized by pressing the MEMORY button, and the frequency is recalled by positioning the SELECT switch as needed.

In the SIMPLEX position, the transceive frequency is locked on the memorized frequency.

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In the TX MR position, the transmitter is locked on the memorized frequency, while the receiver is controlled by the main VFO (or FIX unit).

In the RX MR position, the receiver is locked on the memorized frequency, while the transmitter is controlled by the VFO.

Caution should be observed during repeater operation. If the SELECT switch is in the TX MR position, and the RPT switch is in the NOR position, the 1 MHz shift will be applied to the memorized frequency (which is recalled only for transmission). Unless the operator is careful, an unwanted repeater may be activated, causing interference to other users.

Optional batteries inserted into the MEMORY UNIT will allow the memorized frequency to be held, even though the FT-625RD is turned off.

For most repeater work, the memorized repeater frequency can be recalled by placing the SELECT switch in the SIMPLEX position, and placing the RPT switch in the NOR position. The main VFO may then be turned to another repeater or calling frequency; return to the VFO frequency is performed by placing the SELECT switch in the VFO/FIX position. Alternatively, the repeater input frequency may be memorized and recalled by placing the SELECT switch in the TX MR position. The VFO can then be tuned to the repeater output frequency, and the RPT switch should be turned OFF.

REPEATER OPERATION

The transmit frequency may be shifted 1 MHz for repeater operation. When the RPT switch is in the NOR (normal) position, the transmit frequency is shifted 1 MHz lower than the receive frequency. When the RPT switch is placed in the REV (reverse) position, the receive frequency is shifted 1 MHz lower. Extreme caution should be exercised so as not to transmit outside the amateur bands when using the RPT switch.

In some areas, repeater splits other than 1 MHz have been authorized. In this case, an optional crystal may be installed in the local unit to provide repeater splits of up to 4 MHz. The AUX/1 MHz switch must be placed in the AUX position for actuating the optional crystal.

Determination of the AUX crystal frequency is made as follows:

Band 51 (51.0-52.0 MHz)

(71.01 - Shift frequency)

Band 52 (52.0-53.0 MHz)

(72.01 - Shift frequency)

Band 53 (53.0-54.0 MHz)

(73.01 + Shift frequency)

Example

Calculate the crystal frequency for -1.2 MHz shift in the 53 MHz band segment (TX frequency 1.2 MHz lower):

73.01 - 1.2 = 71.81

When the optional memory unit is installed, the output frequency of the repeater may be stored by pressing the MEMORY button and placing the SELECT switch in the SIMPLEX position. By placing the RPT switch in the NOR or REV positions, the desired offset will occur. If the repeater input and output frequencies are within the same 1 MHz width of the BAND switch, the input frequency may be stored in memory, and then recalled for transmission only by placing the SELECT switch in the TX MR position. The VFO can then be tuned to the output frequency of the repeater. In this way, "oddball" splits can be accommodated. Tone actuated repeaters can be accessed by means of the built-in tone burst generator, which is activated by pressing the BURST switch on the front panel. With this button depressed, pushing the microphone PTT switch will cause insertion of the burst signal at the beginning of each transmission.

The audio frequency of the tone burst signal may be programmed for any frequency between 671 and 2900 Hz, by use of a crystal and by positioning the selector plug on the tone burst unit. The U.S. model normally is set up for 1800 Hz operation. The chart shows the relation between the position of the selector plug, the crystal frequency, and the tone frequency.

Tone Frequency	Multiplier	Plug Position	Crystal Frequency
671-1342	4096	А	^(kHz) 2750-5500
1343 2685	2048	В	2750 - 5500
2686 - 2900	1024	С	2750-2970

Crystal frequency = Tone frequency \times Multiplier.



CRYSTAL CONTROLLED OPERATION

In addition to normal VFO operation, five crystals may be selected by the channel switch on the front panel for crystal controlled operation. Such operation is often useful for operation on favorite calling or repeater frequencies. Since the 6 meter band is divided into four segments in the FT-625RD, these five crystals could provide for operation on 20 different frequencies.

The crystal holders accept standard HC-25/U type crystals. All crystal frequencies must fall between 8,200 kHz and 9,200 kHz. A trimmer capacitor is connected in series with each crystal to permit fine tuning of the crystal frequency; Adjustment of this trimmer will move the crystal frequency approximately 1 kHz.

The correct crystal frequency for any desired operating frequency may be determined by using the following formula:

 $f_x = f_1 - f_0$

where $f_x = crystal$ frequency $f_0 = operating$ frequency $f_1 = a$ constant shown in Table 1

Example: Calculate the required crystal frequency for 50.105 MHz CW operation.

 $f_x = f_1 - f_0 = 59.1993 - 50.105 = 9094.3 \text{ kHz}$

It can be seen from the chart that a crystal for 50.51 MHz FM can also be used for 51.51, 52.51, and 53.51 MHz FM by changing the position of the BAND switch.

BAND	f 1			
(MHz)	LSB(MHz)	USB(MHz)	FM (MHz)	AM · CW (MHz)
50	59.2015	59.1985	59.2	59.1993
51	60.2015	60.1985	60.2	60.1993
52	61.2015	61.1985	61.2	61.1993
53	62.2015	62.1985	62.2	62.1993

Table 1

CW FILTER INSTALLATION

- 1) Remove the top cover by releasing the fasteners marked "A" in Figure 1. Slowly lift the cover, and remove the speaker lead, marked "B", from the speaker lugs.
- 2) Remove the plate marked "C" as shown in Figure 1.
- 3) Remove the screws marked "D" in Figure 1, and carefully remove the Filter Unit from its edge connector.
- 4) Install the CW filter on the Filter Unit as shown in Figures 2 and 3. Slide the mounting lug and leads into the holes on the circuit board, make the mounting nut snug, and solder the two leads to the circuit board, as shown in Figure 2.
- 5) The jumper shown in Figure 3 must be moved to the position shown in the drawing.
- 6) Replace the circuit board, covering plate, speaker lead, and the top cover of the transceiver. Installation is now complete.





Fig. 2



Fig. 3

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CIRCUIT DESCRIPTION

GENERAL

The block diagram and the following circuit description will provide you with a better understanding of this transceiver. The discussion will be on a module-by-module basis, in the interest of clarity.

Each circuit board has its own parts numbers, beginning, usually, with the number ____01. For example, RF amplifier transistor type 3SK59Y on PB-1853 is Q_{101} .

The FT-625RD utilizes single conversion on SSB and CW, with a 10.81 MHz IF. On AM and FM, double conversion is used, with a 455 kHz second IF.

RECEIVER

RF UNIT (PB-1853)

The 50 MHz signal from the antenna is switched from the BOOSTER UNIT (**PB-1859**), where the input signal has passed through a lowpass filter (L_{810} , L_{811} , C_{825} – C_{827}), to pin 2 of the RF UNIT. The signal is amplified by RF amplifier Q₁₀₁ (**3SK59Y**) and fed to gate 1 of the first mixer, Q₁₀₂ (**3SK51**). The input and output circuits of the RF amplifier utilize a double tuned circuit, which is sharply tuned to the center of the band by varactor diodes D₁₀₁, D₁₀₃, and D₁₀₄ (**1S2209**), thus minimizing cross modulation and intermodulation effects. A local signal is generated in the PREMIX UNIT (PB-1861), filtered by T_{104} , C_{113} , and D_{106} (1S2209), and fed to gate 2 of Q_{102} . Here the 60.81–64.81 MHz local signal is mixed with the 50–54 MHz incoming signal, producing a 10.81 MHz IF. The IF signal is passed through crystal filter XF₁₀₁. which has a 3 dB bandwidth of 30 kHz, and is amplified by IF amplifier Q₁₀₄ (3SK59Y). The SSB and CW signals are fed to the FILTER UNIT, while AM and FM signals are fed to the FM IF UNIT.

FM IF UNIT (PB-1856)

The FM or AM signal delivered from the RF UNIT is fed to pin 7 of the FM IF UNIT. The signal is amplified by IF amplifier Q_{505} (**3SK59Y**), and delivered to ceramic filter CF501, which has bandwidth of 300 kHz. From here the signal is fed second mixer Q_{507} (**2SC1815Y**), where the IF signal is mixed with an 11.265 MHz signal generated by second heterodyne oscillator Q_{506} (**2SC1815Y**), thus producing a 455 kHz second IF. The second IF signal is passed through ceramic filters CF₅₀₂ and CF₅₀₃.

An FM signal is amplified by IF amplifiers Q_{509} and Q_{510} (2SC1815Y), and fed to amplifier limiter Q_{511} (μ PC577H), which removes any amplitude modulation component of the signal. The signal is then passed to ceramic discriminator CD₅₀₁ (SFD455S4), which produces an audio output in response to a corresponding frequency or phase shift in the 455 kHz IF signal. The output of CD501 is amplified by Q_{515} (2SC1815Y) and delivered to the AF UNIT.



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An AM signal is amplified by buffer amplifier Q508 (2SC1815Y), passed through ceramic filter CF504, and amplified by IF amplifiers Q516 (3SK59Y), and Q517 (2SC1815Y). The output of Q517 is detected by AM detector D510 (1S188FM), amplified by Q519 (2SC1815Y), and passed to the AF UNIT.

A portion of the output of Q_{517} is detected by D_{508} and D_{509} (**1S188FM**), amplified by Q_{518} (**2SC1815Y**), and then fed to the second gates of Q_{505} and Q_{516} for AGC (Automatic Gain Control) purposes.

NB UNIT (PB-1866)

SSB and CW signals from XF₁₀₁ on the RF UNIT are amplified by buffer amplifier Q₁₀₃ (2SK19GR) and delivered to pin 11 of the NB UNIT. The 10 MHz IF signal is amplified by buffer amplifier Q₁₇₀₁ (2SC1815Y) and fed to noise blanker mixer Q₁₇₀₃ (3SK40M); here the 10.7 MHz IF signal is mixed with a local signal generated by Q₁₇₀₂ (2SC1815Y), producing a 455 kHz noise blanker IF. This signal is amplified by Q₁₇₀₄ and Q₁₇₀₅.



When a carrier or noise-free modulated signal is received, the 455 kHz signal is rectified by D_{1701} and D_{1702} (1S1007), charging C_{1719} . There is no discharge loop for C_{1719} ; therefore, signals which exceed the charged voltage established by the reference voltage on C₁₇₁₉ will not pass through D₁₇₀₁ and D₁₇₀₂. Accordingly, there will be no voltage drop across R1727, and Q1707 (3SK40M) will conduct as the gate voltage approaches zero. When Q_{1707} conducts, the voltage applied to the base of Q105 (2SC1815Y) will drop. As the drain voltage of Q1707 drops, the base voltage of Q105 drops, turning the latter off. The collector voltage will then increase, producing a forward bias to gate 2 of IF amplifier Q_{104} , allowing normal operation of Q104.

When pulse noise is received which exceeds the charged reference voltage established by C_{1720} , D_{1701} and D_{1702} will permit negative-going pulses to turn Q_{1707} off. The drain voltage will increase rapidly as it turns off.

When no carrier is present in the 455 kHz IF, the noise at the discriminator output is amplified by

 Q_{513} and $Q_{514}(2SC1815Y)$ and detected by D_{505} and $D_{506}(1S188FM)$, producing a DC voltage. This voltage turns squelch controller $Q_{512}(2SC1815Y)$ on; with Q_{512} on, the base of Q_{515} is grounded, quieting the audio amplifier. When a carrier is present, the quieting action of the receiver removes noise from the discriminator output, and Q_{512} is turned off, permitting normal operation of Q_{515} .

As the drain voltage increases, Q_{105} will turn on, and the collector voltage will decrease. Accordingly, gate 2 of Q_{104} will be biased to block the signal flow momentarily in the presence of the noise pulse.

 Q_{1706} (2SC1815Y) samples the output of Q_{1705} , providing AGC control action on Q_{1704} and Q_{1705} .

FILTER UNIT (PB-1855)

SSB and CW signals from pin 7 of the RF UNIT appear at pin 17 of the FILTER UNIT. The 10.81 MHz signal is amplified by buffer amplifier Q_{301} (2SK19GR) and passed through SSB filter XF₃₀₁ or optional CW filter XF₃₀₂. The filtered IF signal is amplified again by buffer amplifier Q_{302} (2SK19GR) and passed to the SSB IF UNIT.



SSB IF UNIT (PB-1854)

The 10.81 MHz filtered IF signal from pin 2 is amplified by Q_{201} , Q_{202} , and $Q_{203}(3SK59Y)$ and delivered to SSB detector $Q_{204}(\mu PC1037H)$, where the signal is joined with the BFO signal from the MIC AMP UNIT. The resulting audio signal exits the circuit board at pin 15, passes through the mode switch, and reappears at pin 6, where it is fed to amplifier Q_{209} (2SC1000GR). The audio response is then shaped by Q_{210} (2SC1815Y), which acts as an active low-pass filter; the signal is then delivered to the AF UNIT.

A portion of the output of Q_{203} is detected by D_{202} and $D_{203}(1S188FM)$, amplified by buffer amplifier $Q_{207}(2SC1815Y)$ and delivered to AGC amplifier Q_{208} (2SC1815Y), which controls the gain of the IF and RF amplifiers. A further sampling of the signal is made at the output of Q_{208} ; this signal is amplified by buffer $Q_{205}(2SK19GR)$ and DC amplifier $Q_{206}(2SA564AR)$, and this DC voltage produces an indication of received signal strength on the S-meter.

AF UNIT (PB-1764)

The audio signals are passed via the mode switch to pin 13 of the AF UNIT, with SSB and CW signals passing through Q_{209} and Q_{210} . The signal is amplified by $Q_{402}(2SC372Y)$, $Q_{403}(2SC711D)$, $Q_{404}(2SA695)$, $Q_{405}(2SD359)$, and $Q_{406}(2SB529)$, delivering 3 watts of audio output to the speaker through an OTL (output transformerless) circuit configuration.

The output of sidetone oscillator $Q_{418}(2SC373)$ is fed to Q_{402} .

In the FM mode, a DC voltage at the discriminator is applied to differential amplifier Q_{416} and Q_{417} (2SK30AY). When the frequency of the received signal is shifted from the discriminator center, the resulting DC voltage causes either Q_{416} or Q_{417} to conduct, and the amount of shift is displayed on the meter when the meter switch is in the DISC position.





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TRANSMITTER

The discussion of the transmitter section of the FT-625RD will be done on a mode-by-mode basis.



SSB TX SIGNAL PATH

SSB

MIC AMP UNIT (PB-1857)

The speech signal from the microphone enters the TONE BURST UNIT at pin 6B, and is amplified by Q_{1201} (2SC1000GR) and buffer amplifier Q_{1203} (2SC1815Y) and fed to pin 3B of the MIC AMP UNIT.

The signal is controlled in amplitude by MIC GAIN control VR_{3a}. The signal is amplified further by Q₆₀₄ (2SC1815Y) and shaped by low-pass filter Q₆₀₅ (2SC1815Y) for delivery to the ring modulator, D₁₀₂₅ $-D_{1208}$ (1S1007).

Carrier oscillator Q_{601} (**2SC1815Y**) oscillates at 10.8115 MHz for LSB and 10.8085 MHz for USB, depending on the position of the mode switch. The output from the oscillator is fed through buffer amplifier Q_{602} (**2SC1815Y**) to the ring modulator. The resulting 10.81 MHz double sideband signal is amplified by buffer amplifier Q_{603} (**2SK19GR**) and fed to the FILTER UNIT through pin 17.

FILTER UNIT (PB-1855)

The 10.81 MHz DSB signal is fed from pin 3 to buffer amplifier Q_{303} (2SC1815Y). From here the signal passes through diode switch D_{303} (1S1007), is filtered by XF₃₀₁, and the resulting SSB signal passes through diode switch D_{306} (1S1007) to buffer amplifier Q_{304} (2SK19GR). The amplified SSB signal is fed from pin 13 to the NB UNIT.

NB UNIT (PB-1866)

The SSB signal is fed from pin 17 to buffer amplifier Q_{1078} (2SC1815Y), and from there the signal is applied to the bases of Q_{1709} and Q_{1710} (2SC1815Y). When the RF processor switch is OFF, the SSB signal is amplified by Q_{1709} and fed to Q_{1712} (3SK59Y).When the processor switch is ON, the SSB signal is amplified by Q_{1710} and further amplified by limiter Q_{1711} (TA7060P), where the signals that exceed the preset clipping level are sliced out. This highly clipped SSB signal is passed through a selective filter, XF₁₇₀₁, to remove RF harmonics that result from clipping. The filtered output signal is amplified by Q_{1712} and fed to the EXCITER UNIT.



EXCITER UNIT (PB-1858)

The SSB signal from pin 2 is fed to the balanced mixer, Q_{701} (MC1496G), where the SSB signal is heterodyned to the desired RF frequency by mixing with the 60.81–64.81 MHz local signal supplied from the PRE MIX UNIT. The output signal from the balanced mixer passes through tuned circuits consisting of $T_{701}-T_{705}$, which are tuned by varactor diodes $D_{702}-D_{705}$ and D_{707} (1S2209), in which voltages are preset according to the position of the bandswitch. In this manner, the circuit is tuned exactly to the operating frequency, and spurious radiation is effectively eliminated.

The signal is then amplified by Q_{702} (**3SK59Y**), Q_{703} (**2SC2053**), and Q_{704} (**2SC730**), providing 0.2 watts of drive to the BOOSTER UNIT.

BOOSTER UNIT (PB-1859)

The signal from the EXCITER UNIT is fed to the BOOSTER unit's driver amplifier Q_{801} (2SC1945D) and to power amplifiers Q_{802} and Q_{803} (2SC2099), providing 25 watts of RF output. The signal is fed through a low-pass filter to the antenna jack.

A small portion of the output is rectified by D_{804} , and the resulting DC voltage is fed to the meter, where an indication of relative output power is provided.

A further sampling of the RF output is made by D_{805} (1S188FM), and the resulting DC voltage is amplified by Q_{707} (2SC1815Y) and applied to ALC amplifier Q_{706} , which controls the gain of Q_{702} . In the presence of high SWR, the drive level through the EXCITER UNIT is reduced, thus protecting the final transistors.

The bias to Q_{802} and Q_{803} is stabilized by Q_{804} (2SC496O) at 9 volts, and it is controlled by diodes D_{802} and D_{803} (10D1), providing further protection for the final transistors.





AM

The AM signal path is identical to that for SSB until the signal reaches Q_{605} . At this point, the signal is delivered to AM modulator Q_{609} (**3SK40M**). The AM carrier is generated at 10.8107 MHz by oscillator Q_{606} (**2SC1815Y**), amplified by buffer Q_{608} (**2SC1815Y**), and fed to Q_{609} . The output of Q_{609} is delivered to pin 2 of the EXCITER UNIT, and from there to amplifier Q_{1712} . The signal then is amplified in the same way as the SSB signal, for delivery to the antenna.

CW

In the CW mode, the carrier generated for AM by Q_{606} is used. The key line is connected to sidetone oscillator Q_{418} , the output of which is fed to Q_{402} for sidetone monitoring, as well as to VOX amplifier $Q_{407}(2SC372Y)$ for semi-break-in operation.

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The key line is also fed to a flip-flop circuit in Q_{1207} (MC14011B), which provides the high-low output to drive keying switch Q_{1208} (2SC1815Y), Q_{1208} keys both Q_{609} and Q_{702} , providing a stable, chirp-free CW signal. Shaping is applied to the output of Q_{1208} to remove any trace of key clicks.

FM

The speech signal for FM is amplified by microphone amplifier Q_{610} (2SC1000GR), and is further amplified by Q_{611} (2SC1815Y). The amplified signal is fed to the instantaneous deviation control (IDC), consisting of diodes D_{616} and D_{617} (1S1555), which clips both positive and negative peaks.



FM TX SIGNAL PATH

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The output from the IDC is amplified by Q_{612} (2SC1815Y), and fed through active low-pass filter Q_{613} (2SC1815Y), which removes harmonics above the speech range caused by clipping. The speech signal is then applied to phase modulator varactor diode D_{610} (1S2209), which varies the frequency of the 10.81 MHz modulator oscillator, Q_{607} (2SC1815Y). The frequency modulated signal is amplified by buffer amplifiers Q_{608} (2SC1815Y) and Q_{609} (3SK40M), passed to the NB UNIT, where it is amplified by Q_{1712} , and then fed to Q_{701} for conversion to 50–54 MHz by mixing with the 60.81–64.81 MHz local signal. From there, the signal is amplified as on the other modes.







COMMON CIRCUITS

CARRIER GENERATION

 Q_{601} , located on the MIC AMP UNIT, generates an LSB carrier of 10.8085 MHz and a USB carrier of 10.8115 MHz. The AM and CW carrier is generated at 10.8107 MHz by Q_{606} .

VFO UNIT (PB-1774)

A modified Colpitts oscillator is used to generate a 1 MHz tuning range for the VFO of 8.2-9.2 MHz. The oscillator signal generated by $Q_{1301}(2SC372Y)$ is varied by VC₁₃₀₁, which is geared to a precision dial tuning mechanism. Temperature compensation is provided for by sub-blades of VC₁₃₀₁.

The output from the VFO oscillator is amplified by buffer amplifiers $Q_{1302}(2SK19GR)$ and Q_{1303} (2SC372Y) and delivered to the FIX UNIT.

FIX UNIT (PB-1750-3380)

In addition to VFO operation, 5 crystal controlled channels may be employed for fixed frequency operation. Selection of the crystal channel or VFO operation is made by the selector switch on the front panel.

The FIX channel crystal oscillator Q_{901} (2SC372Y) oscillates at a frequency between 8.2 and 9.2 MHz. The output is fed through buffer amplifier Q_{902} (2SC372Y) to the PREMIX UNIT. Trimmer capacitors $TC_{901}-TC_{905}$ provide for precise adjustment of the crystal frequency.

The VFO signal also passes through buffer Q_{902} and is passed to the PREMIX UNIT.

LOCAL UNIT (PB-1840)

A premix local signal of 70.01-73.01 MHz is generated by Q_{1001} (2SC785BN) and amplified by buffer amplifier Q_{1002} (2SC372Y). This signal is delivered to the PRE MIX UNIT for mixing with the VFO signal. The frequency mixing scheme is shown in Figure 4.

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PREMIX UNIT (PB-1861)

The premix system utilizes double balanced mixer Q_{1001} (MC1496G). Here the premix local signal at 70.01–73.01 MHz is mixed with the VFO signal at 8.2–9.2 MHz, yielding an output local signal of 60.81–64.81. This frequency range, when mixed with the incoming RF signal, yields the first IF of 10.81 MHz.

The output from Q_{1101} is passed through a bandpass filter consisting of T_{1101} , T_{1103} , and varactor diodes $D_{1101} - D_{1103}$ (1S2209). The filtered signal is amplified by buffer Q_{1102} (3SK59Y) and delivered to the COUNTER BUFFER UNIT, RF UNIT, and the EXCITER UNIT.



COUNTER BUFFER UNIT







BAND(MHz)	FA (MHz)	FB (MHz)	Fout (MHz)
50,0-51.0	70.01		60.81-61.81
51.0-52,0	71.01		61.81-62.81
52.0-53.0		SE QE	62,81-63,81
53.0-54.0			63,81-64,81





COUNTER UNIT (PB-1867)

The frequency of operation is indicated in MHz, kHz, and to 100 Hz resolution by six large lightemitting diode display digits.

The signal from the PREMIX UNIT is amplified by $Q_{1801}(2SK19GR)$ and fed to double balanced mixer $Q_{1802}(SN76514)$. Here the 60.81–64.81 MHz premix signal is mixed with a local signal from the OSC UNIT of 56.81 MHz, producing a 4–8 MHz signal at its output.

The 4–8 MHz signal is amplified by Q_{1803} (2SC-784R), and fed through a wave shaper, Q_{1804} (2SC372Y), to counter gate Q_{1807} (F4011), which counts the pulses which pass while the gate is open. The pulses are fed to the six digit decade counter, Q_{1806} (TC5032P), which counts 100 Hz, 1 kHz, 10 kHz, 100 kHz, and 1 MHz. The BCD output signal from Q_{1806} is fed through LED dimmer Q_{1802} (MSM561) and Q_{1813} – Q_{1819} (2SC496) to the display LED's, DS₀₁–DS₀₆ (HP5082–7740). Q_{1821} – Q_{1823} (SN75453) act as a series of switches operated by a timing signal delivered from Q_{1806} to select the output of Q_{1806} which drives the display in the sequence 100 Hz, 1 kHz, 10 kHz, 100 kHz, 100 kHz, 1 MHz.

When the transceiver is tuned below 50.000 MHz or above 53.999 MHz, $Q_{1811}(2SC372Y)$ and Q_{1812} (2SC496) generate a blanking signal to the LED drivers.

OSC (COUNTER LOCAL) UNIT (PB-1869)

This unit is used to generate a 56.81 MHz heterodyne signal for oscillates at 14.20269 MHz for USB/CW, and 14.20223 MHz for AM, FM, and LSB. Its output is multiplied by 4 by doublers Q_{2103} and Q_{2104} (2SC710), producing the 56.81 MHz signal. A diode switch in series with crystal X₁₈₀₁ provides frequency compensation when the mode is changed.





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POWER SUPPLY and REGULATOR UNIT (PB-1858)

The power supply has been designed for operation from 100/110/117/200/220/234 volts AC, 50/60 Hz, or 12 volts DC, negative ground. Inserting the appropriate power cord into the rear panel receptacle makes the connections necessary for operation from the AC or DC supply.

For AC operation, the DC voltage is supplied from bridge rectifier unit D_2 (S15VB10), which is connected to a 20 volt, 6 amp secondary winding of the power transformer. The DC voltage is stabilized at 13.8 volts by the voltage regulator circuit consisting of Q_{1401} (2SD313), Q_{1402} (2SC372Y), Q_1 (MJ802) and D_{1402} (WZ-090).

Since such circuits as the VFO, FIX, and LOCAL units require an extremely stable voltage, the 13.6 V DC supply is further stabilized at 8 volts by Q_{1404} (μ PC14308).

 Q_{1403} acts as a switch to disable the voltage regulators when the current exceeds a preset value.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4 of the power receptacle. To protect the circuits from reversed polarity of the DC voltage, D_1 (U05B) conducts heavily under reversed polarity conditions to blow the line fuse in the DC cord.

VOX OPERATION

A portion of the speech input from the microphone is amplified by $Q_{407}(2SC372Y)$ on the AF UNIT, passed through VOX GAIN control VR_{4a}, further amplified by $Q_{408}(2SC372Y)$, and applied to the base of $Q_{409}(2SC373)$, Q_{409} conducts with the speech signal, causing the collector to reach the "low" state. When a speech signal is not present, Q_{409} cuts off, and the voltage across C_{424} becomes "high".

C₄₂₄, VR₄₀₁, R₄₃₄, and R₄₃₇ form the delay circuit to adjust the VOX relay hold time. The collector voltage is applied to NAND gate Q₄₁₅ (MC14011B), causing pin 8 to become "high".When pins 8 and 9 are "high", pin 10 becomes "low", causing Q₄₁₀ (2SC373) to cut off. In turn, relay controller Q₄₁₁(2SC735) actuates the VOX relay.

The antitrip circuit provides a bucking voltage to prevent the speaker output from tripping the transmitter. The receiver audio output is connected through ANTITRIP potentiometer VR₄₀₂ to the antitrip amplifier, Q₄₁₄ (2SC372Y). Amplifier Q₄₁₃ (2SC373) conducts with the rectified voltage provided from D₄₀₃ (1S1555), thus keeping the potential at pin 9 of Q₄₁₅ "low", maintaining Q₄₁₅ in an "off" configuration while receiving.



The collector voltage of Q_{413} is also fed to the base of Q_{412} , which conducts with high collector voltage on Q_{413} , causing Q_{414} to become "high" rapidly for immediate relay actuation when a speech signal appears in the microphone circuit.

CW SIDETONE

Tone oscillator Q_{418} (2SC373) operates when the MODE switch is in the CW position. It is a phase shift oscillator, operating at approximately 800 Hz.

The tone output is activated by the keying circuit through the emitter circuit of Q_{418} . It is coupled through sidetone level control VR₄₀₃ to the receiver audio amplifier Q_{403} for sidetone monitoring. The output from Q_{418} is also coupled to VOX amplifier Q_{408} for semi-break-in operation.

ALC

A small portion of the output from the EXCITER UNIT is rectified by diodes D_{709} and D_{710} (1S1555) and the resulting DC voltage is amplified by Q_{705} (2SC784R) and Q_{706} (MPSA13). The output of Q_{706} is applied to the gate of Q_{1712} and Q_{702} . ALC bias control VR₇₀₁ controls the bias applied to Q_{706} , and the gain of Q_{1712} and Q_{702} can then be controlled to limit the drive applied to the final amplifier, preventing any distortion caused by overdrive.

TONE BURST UNIT (PB1862)

When the PTT switch is closed, a DC voltage is applied to trigger Q_{1204} (MC14011B), a NAND gate which produces a pulse of 0.5–1 second duration. The pulse switches $Q_{1205}(2SC1815Y)$ to supply DC voltage to $Q_{1206}(MSM5576)$, where the clock signal is divided by 1024, 2048, or 4096, producing an accurate tone burst signal. This signal is fed to the base of the microphone amplifier Q_{610} . The tone length is set by VR₁₂₀₉, and the level is set by VR₁₂₁₀.

AMGC

The AMGC circuit is located on the FM IF UNIT, and is used to reduce the gain of the microphone amplifier when only low-level background noise is present (no speech input from the operator). The microphone signal is fed to pin 17 of the circuit board, is amplified by Q_{501} (TA7063), and is delivered to Q_{502} (2SC1815Y). When a sufficient level of speech input is applied to the microphone,

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 Q_{502} conducts, causing the output of NAND gate Q_{503} (MC14011B) to be "low". This condition cuts off AMGC controller Q_{504} (2SC1815Y). The collector circuit of Q_{504} is connected to the base of the microphone amplifier, Q_{1202} .

When the microphone input signal strength becomes significantly lower than the normal speech level (background noise only), Q_{502} turns off, causing the output of Q_{503} to be "high". This condition causes Q_{504} to conduct, grounding the output circuit of Q_{1202} .

VR₅₀₂ controls the gate holding time.

MAINTENANCE & ALIGNMENT

GENERAL

Your FT-625RD transceiver has been carefully aligned and tested at the factory prior to shipment. The reliability of the solid-state devices used in the FT-625RD should provide years of trouble-free service if the transceiver is not abused, and if routine maintenance is carried out.

The following precautions should be observed, so as to prevent damage to the transceiver:

- (1) Do not interchange the AC and DC power cords.
- (2) Do not apply any AC voltage other than that voltage determined by the transformer primary winding.
- (3) When replacing fuses, be certain to use a fuse of the proper rating for the voltage being used.
- (4) Do not exceed 14 volts DC, at the POWER receptacle, for DC operation. When operating mobile, the battery voltage should be measured with the battery under load (transmitter "keyed" in the FM mode), with the engine running fast enough so that the ammeter shows a "charge". In addition, do not

operate the FT-625RD if the supply voltage is less than 12 volts DC.

(5) Avoid direct exposure to sunlight or water.

ROUTINE MAINTENANCE

Routine maintenance should be limited to keeping the transceiver clean, and performing occasional performance checks of the transmitter RF power output and the receiver sensitivity.

Cleaning:

When the transceiver has been used in a dusty or sandy environment, the interior should be cleaned periodically. A vacuum cleaner or low pressure air blower should be used.

Accumulated dirt may be removed with a soft brush. Check that the interior is thoroughly dry before replacing the cabinet and/or operating the equipment. Wipe the exterior with a damp cloth when necessary.

PERFORMANCE CHECKS

Make all performance checks at 13.6 volts DC (under load), or on the appropriate AC voltage as determined by the transformer primary wiring.



COUNTER UNIT (PB-1867)

TOP VIEW

UNIT (PB-1862)

(PB-1764-3380) FM IF UNIT (PB-1856)

FILTER UNIT (PB-1855) SSB IF UNIT (PB-1854) MIC AMP UNIT (PB-1857) OSC UNIT (PB-1869)

Check the transmitter as follows:

- (a) Connect a suitable 50 ohm dummy load/RF wattmeter to the ANT receptacle.
- (b) Set the MODE switch to the FM position, and key the transmitter while observing the power output, which should be approximately 25 watts. At full power, the S-meter should indicate between 6 and 8 on the relative power output scale.
- (c) Set the MODE switch to SSB, and key the transmitter. Speak in a normal voice into the microphone. The output meter should indicate between 3 and 5 nominally.

Check the receiver sensitivity as follows:

- (a) Connect an AC VTVM to the SP jack. Set the MODE switch to the FM position, and set the SQUELCH control fully counterclockwise.
- (b) Connect the RF output of a precision VHF signal generator to the ANT receptacle and note the VTVM reading with no signal input. Adjust the AF GAIN control and the VTVM range, as required, to obtain a full scale VTVM reading. Do NOT change the setting of the AF GAIN control after this calibration has been made.
- (c) Set the signal generator to the receiving frequency of the transceiver, and adjust the output amplitude of the signal generator until the

VTVM reads 1/100th (20 dB decrease) of the reading in step (b). The signal generator output voltage at this point is the 20 dB quieting sensitivity, and it should be approximately $0.35 \ \mu V$.

- (d) Set the MODE switch to SSB, and connect the AC VTVM to the speaker output. Apply an unmodulated 0.5 μV signal from the signal generator, and tune the transceiver tuning dial for a maximum VTVM reading.
- (e) Advance the RF Gain control to the fully clockwise position, and adjust the AF GAIN control for a reading of 450 mV on the VTVM.
- (f) Reduce the signal generator output, and read the VTVM; the VTVM reading should be less than 45 mV for a 10 dB S/N ratio.

If the above checks indicate a need for realignment, it is recommended that the unit be returned to the dealer for this procedure. Alignment requires special test equipment not normally available to the average station owner. Adjustment of the tuned circuits without the proper equipment or technical expertise will result in degraded transceiver performance.



BOTTOM VIEW

ALIGNMENT

SOME OF THE FOLLOWING PROCEDURES REQUIRE SPECIAL TEST EQUIPMENT AND TECHNICAL KNOWLEDGE, AND SHOULD BE PERFORMED ONLY BY AN EXPERIENCED TECHNICIAN.

AF UNIT (PB-1764A-3380)

(1) CW Semi-break-in

Adjust VR401, the DELAY control, for the desired relay hold time.

(2) CW Sidetone Level

Adjust VR403 for the desired sidetone level.

(3) Antitrip

Set the ANTITRIP control, VR402, to the minimum point that will prevent the speaker output from activating the VOX.

(4) Discriminator Center Meter

Set the controls as f	ollows:
CHANNEL	VFO
MODE	FM
DISC	OFF (S-meter position)
RF GAIN	
	ON (Analog model; for 625RD, connect signal
	generator to antenna receptacle)

Tune the transceiver for a maximum S-meter reading on the marker or signal generator signal. Tune the main dial so as to find the center of the maximum signal indication. Place the meter switch in the DISC position, and adjust VR_{404} so that the meter pointer is exactly at midscale on the meter. Check to see that the meter moves an equal amount on either side of the center for an equal frequency excursion.

Shift the VFO frequency 10 kHz higher than the reference signal, and adjust VR₄₀₅ for a meter reading of 8 on the PO scale.



AF UNIT (PB-1764-3380)

SSB IF UNIT (PB-1854)

(1) S-Meter Setting

Disconnect the antenna from the coax receptacle. Set the MODE switch to AM, and set the RF GAIN control to the fully counterclockwise position. Adjust VR₂₀₂ (FULL SCALE) until the meter reads full scale.

Place the RF GAIN control in the fully clockwise position, and connect a signal generator to the antenna receptacle. Set the output of the signal generator to +3dB at 52 MHz, and tune the receiver to the generator signal. Place the TUNE control in the 12 o'clock position, and adjust VR₂₀₁ for a reading of S1 on the meter.

Set the output of the generator to +20 dB, and adjust VR₂₀₃ for a reading of S9 on the meter.

These adjustments should be repeated several times, in order to secure proper calibration of the S-meter.



SSB IF UNIT (PB-1854)

MIC AMP UNIT (PB-1857)

(1) SSB Carrier Frequency

Connect a 50 ohm dummy load, such as the Yaesu YP-150, to the antenna receptacle, and connect the output of an audio oscillater to the microphone input. Set the MODE switch to an SSB mode. Apply a 1500 Hz tone to the microphone input, and adjust the SSB MIC GAIN or the audio output to secure an RF output of 5 watts. Without changing the level, change the audio frequency to 300 Hz, and adjust TC₆₀₁ for LSB and TC₆₀₂ for USB to obtain 2 watts output. Change the audio frequency to 2700 Hz, the output should be 2 watts.

(2) AM/CW Carrier Frequency

Tune the transceiver in the USB mode into a dummy load, and use a separate receiver to monitor the transmitted signal. Tune the external receiver until the transmitted voice quality is natural. Change the FT-625RD to AM (leave the external receiver in USB), and rotate the main dial 800 Hz higher in frequency as shown on the digital display (4/5 of 1 kHz division on analog display). Adjust TC_{604} for a zero beat in the monitor receiver when the transmitter is keyed.

(3) Carrier Balance

Connect a dummy load to the antenna receptacle, and the RF probe of a VTVM to the center conductor of the antenna receptacle. Se the MODE switch to LSB. Set the MIC GAIN control to the fully counterclockwise position. Set the VOX GAIN control to the MOX position, and adjust VR_{601} and TC_{603} for a minimum reading on the VTVM. A nominal value will be less than 0.2 V.

Repeat this procedure on USB, then repeat again on LSB, so that a minimum reading is obtained on both sidebands.

(4) AM Carrier Level

Set the MODE switch to AM, and key the transmitter. With no audio input, adjust VR_{2301} (AM CONT UNIT) for a reading of 15 watts into a dummy load/wattmeter.



MIC AMP UNIT (PB-1857)

FIX UNIT (PB-1750-3380)

Precise frequency alignment of optional fixed channel crystals may be made by adjustment TC₉₀₁-TC₉₀₅ for channels 1-5, respectively.



FIX UNIT (PB-1750-3380)

LOCAL UNIT (PB-1860)

Set the BAND switch to 50, and connect precision frequency counter to pin 2 of MJ3. Adjust L_{1001} for a counter reading of 70.010 MHz.

Set the band switch to 51, and adjust L_{1002} for a counter reading of 71.010 MHz.

In like fashion, L_{1003} and L_{1004} should be adjusted for readings of 72.010 and 73.010 MHz, with the BAND switch in the 52 and 53 positions, respectively.



LOCAL UNIT (PB-1860)

PREMIX UNIT

Preset the controls as follows:

CHANNEL	VFO
MAIN DIAL	500
TUNE	
BAND	
RPT	

Connect a dummy load to the antenna receptacle, and connect the DC probe of a VTVM to pin 7 of MJ_6 . Adjust VR_{1201} , located on the BURST/KEYING UNIT, for a reading of 3.2 V on the VTVM.

Adjust the following controls for the readings shown below, for the specified bandswitch positions:

BAND	CONTROL	VTVM READING
51	VR1202	4.2 V
52	VR1203	5.2 V
53	VR1204	6.2 V

Set the BAND switch to 52.

Now connect the RF probe of the VTVM to pin 4 of MJ_6 . Peak $T_{1101} - T_{1104}$, and reset VR_{1101} for a reading of 200 mV. This process should be repeated several times so that the peaking of the transformers corresponds to a 200 mV reading.



PREMIX UNIT (PB-1861)



BURST. KEYING UNIT (PB-1862)

Set the VFO knob to 0. Peak the front panel TUNE control for a maximum reading on the VTVM. Note the position of the TUNE control: this position will be used in future alignment steps, and will be referred to as "52 MHz position". This position should be very close to the 12 o'clock position.

Set the VFO to 500. Set the TUNE control to the 12 o'clock position. Set the BAND switch to 50, and peak VR_{1201} for a maximum reading on the VTVM. Place the BAND switch to 51, and peak VR_{1202} for a maximum VTVM reading. Set the BAND switch to 53, and peak VR_{1204} for a maximum VTVM reading.

Do not adjust VR_{1203} with the BAND switch in the 52 position, because it has already been adjusted.

For peaking of optional auxiliary repeater split crystals, peak $VR_{1205} - VR_{1208}$ for 50–54 MHz, respectively, for a maximum VTVM indication. The RPT switch should be at NOR, and the AUX position should be selected.

EXCITER, BOOSTER UNITS (PB-1858, 1859)

For peaking of the driver and final amplifier stages, preset the controls as follows:

BAND	52
MODE	FM
VFO	
TUNE	52 MHz position

Connect a dummy load/wattmeter to the antenna receptacle.

Connect the RF probe of a VTVM to pin 6 of MJ_5 . Peak T_{1707} for a maximum VTVM reading while transmitting.

Connect the RF probe of the VTVM to pin 17 of MJ_6 . Peak $T_{701}-T_{705}$, TC_{701} , and L_{705} for a maximum reading on the VTVM.

Connect a DC ammeter between the 13.6 V DC line and feedthrough capacitor C_{829} to which the DC line is connected. Set the front panel PWR CONTROL fully counterclockwise, and adjust VR₈₀₁, located on the BOOSTER UNIT, for a reading of 150 mA while transmitting.

Rotate the PWR CONTROL fully clockwise. Rotate VR_{701} and VR_{702} **EXCITER UNIT**) fully clockwise. Adjust $TC_{801} - TC_{803}$ (**BOOSTER UNIT**) for maximum power output as indicated on the wattmeter.



EXCITER UNIT (PB-1858)



BOOSTER UNIT (PB-1859)

- 35 -
ALC, PO METER, and AFP

Connect a DC voltmeter to pin 11 of MJ_6 . Adjust VR_{803} for a minimum voltage reading while transmitting.

While transmitting, adjust VR₇₀₁ (EXCITER UNIT) for a reading of 25 watts on the wattmeter.

While transmitting at full power, adjust VR₈₀₂ for a reading of 8 on the front panel PO meter.

Remove the dummy load from the antenna receptacle. Transmit at full power, and adjust VR₇₀₂ for a reading of 2 on the PO meter.

Connect the dummy load/wattmeter to the antenna receptacle, and place the MODE switch in the AM position. Place the AM carrier control in the 3 o'clock position.

While transmitting, adjust VR_{2301} (AM CONT UNIT) for a reading of 15 watts output on the wattmeter.

Place the MODE switch in the SSB position. Set the MIC GAIN control to the 12 o'clock position, and connect an audio signal generator to the MIC jack. Apply a 1 kHz, 1.5 mV audio signal.

Adjust T_{601} (MIC AMP UNIT) and T_{1704} (NB UNIT) for maximum power output.

Place the PROC switch in the ON position. Adjust T_{1705} and T_{1706} (NB UNIT) for maximum power output.

Connect the DC probe of a VTVM to pin 13 of MJ_6 . Set the output of the audio signal generator to 15 mV. Switch the PROC control on and off, and adjust VR_{1702} (NB UNIT) for an identical VTVM reading with the RF processor on and off.

Turn the PROC switch off, and adjust the audio signal generator to secure a power output of 5 watts while transmitting. Now place the PROC switch ON, and adjust VR_{1701} (NB UNIT) for a reading of 10 watts output on the wattmeter.

NOISE BLANKER ALIGNMENT

Preset the controls as follows:

BAND	. 52
VFO	. 0
TUNE	. 52 MHz position
ATT	. OFF

Connect a signal generator to the antenna receptacle. Apply a 40 dB signal from the generator to the transceiver frequency, and connect a DC voltmeter to TP_{1701} (NB UNIT). Place the NB switch ON.

Adjust $T_{1701}-T_{1703}$ (NB UNIT) for a minimum reading on the DC voltmeter.



NB. PROC UNIT (PB-1866)

RF UNIT

Apply the output from a sweep generator to gate 1 of Q_{102} , located on the RF UNIT. Connect an oscilloscope to the drain of Q_{104} . Adjust T_{105} and T_{106} until the scope pattern shown in Fig. 5 is obtained.



Fig. 5

Set the controls as follows:

BAND				÷		52 MHz
VFO.						0
						52 MHz position

Connect a signal generator to the antenna receptacle.

Apply a 10 dB signal from the signal generator, and tune the generator output to the transceiver receiving frequency. Adjust $T_{101}-T_{104}$ and T_{107} (RF UNIT), T_{301} (FILTER UNIT), and $T_{202}-T_{203}$ (SSB IF UNIT) for a maximum S-meter deflection. The adjustment of these cores should be performed several times to ensure peaking.



RF UNIT (PB-1853)

FM IF UNIT

Preset the controls as follows:

BAND			+					52
VFO.								
TUNE		,						52 MHz position
ATT .								
MODE					•	1	÷	AM

Connect a signal generator to the antenna receptacle, and apply a 20 dB signal to the transceiver frequency. Connect a DC voltmeter to TP_{502} (FM IF UNIT).

Adjust T_{501} , T_{503} , and T_{504} for a minimum reading on the voltmeter.

Place the MODE switch in the FM position, and set the signal generator output to 40 dB. Connect the DC voltmeter to TP_{so1} (FM IF UNIT).

Adjust T₅₀₂ for a maximum reading on the voltmeter.



FM IF UNIT (PB-1856)

SQUELCH LEVEL ALIGNMENT

Press the controls as follows:

BAND	52	
VFO	0	
	52 MHz positio	n
MODE	FM	
ATT	OFF	

Connect a signal generator to the antenna receptacle. Apply a 0 dB, 1 kHz modulated tone (70% modulation) to the transceiver frequency. Rotate the SQUELCH control fully clockwise. Adjust VR₅₀₃ (FM IF UNIT) to the threshold point where the receiver is just silenced.

Remove the generator signal. With no signal present, the receiver should remain quieted until the SQUELCH control is rotated to approximately the 10 o'clock position.

AMGC ALIGNMENT

Connect a DC voltmeter to pin 4A of MJ_8 . Apply an audio signal of 1 kHz @ 0.7 mV to the microphone jack. Place the AMGC switch in the ON position, and adjust VR₅₀₁ (FM IF UNIT) for a reading of 8 volts on the voltmeter.

Set the audio input level to 0.8 mV, and adjust VR_{501} for a reading of 0 volts.

Now adjust the delay time for the AMGC. Remove the audio input, and after 0.5 second, the voltage should again read 8 volts. VR₅₀₂ adjusts the delay time. Clockwise rotation increases the delay time.

FM DEVIATION ADJUSTMENT

Connect a dummy load and an FM deviation meter to the antenna receptacle, and connect the output of an audio signal generator to the microphone input. Set the MODE switch to FM, set the BAND switch to 52, the VFO to 0 and the TUNE control to the 52 MHz position, Refer to Fig. 6.

Set VR₅₀₁ (MIC AMP UNIT) fully clockwise, and set VR₅₀₄ to the center of its range.

Connect a frequency counter to pin 12 of the MIC AMP UNIT, and ensure that the audio signal generator is off. Adjust L_{604} for a reading of precisely 10.8100 MHz on the counter.

Apply a 1 kHz, 25 mV signal from the audio generator. Adjust VR_{602} for a deviation of 5 kHz. Now reduce the audio input level to 2.5 mV. Adjust VR_{603} for a deviation of 3.5 kHz.







Fig. 6

COUNTER UNIT

Apply the output from a sweep generator to the gate of Q_{1801} (COUNTER UNIT). Connect an oscilloscope to pin 2 of Q_{1802} . Adjust T_{1801} and T_{1802} until the waveform shown in Fig. 7 is obtained.





COUNTER LOCAL ALIGNMENT

Connect a DC voltmeter to TP_{2101} (COUNTER LOCAL UNIT). Place the MODE switch in the AM position. Adjust T_{2101} and T_{2102} for a maximum reading on the voltmeter.

Connect a 56 ohm resistor between pin 6 of PB-1802 (connector board for PB-1869) and ground. Connect the RF probe of a VTVM to pin 6. Adjust T_{2103} and T_{2104} for a maximum reading on the VTVM.

Disconnect the VTVM, and connect a precision frequency counter to pin 6. Adjust the trimmer capacitors shown for the MODE switch positions indicated in the chart below.

MODE	TRIMMER	FREQUENCY
USB	TC2101	56.8115 MHz
CW	TC2102	56.8107 MHz
FM	TC2103	56.8100 MHz
LSB	TC2104	56.8085 MHz





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MARKER CALIBRATION (FT-625R only)

Place the MARK switch in the ON position. Pin 10 of the MARKER UNIT is the output of the marker. Use the fundamental output of a frequency counter such as the Yaesu YC-500, and adjust TC_{2201} for a zero beat against the harmonic from the frequency counter.



MARKER UNIT (PB-1802)





VFO COMPARTMENT

REG UNIT

 VR_{1401} provides adjustment of the 13.6 V DC output from the REG UNIT. The test point is shown in the photograph.



Regulator unit (PB-1756)

	MAIN	CHASSIS			POWER TRANSFORMER
Symbol Number	Parts Number	Description	PT1	52000052	52-56 # 230015F
	Number	IC & TRANSISTOR		_	
Q2,5	25000116	IC			
Q3	25000109	<i>μ</i> PC14305			
Q1	22490003	Transistor MJ-802			METER
			M1(with PL3)	74000370	SP-38A
		DIODE			· · · · · · · · · · · · · · · · · · ·
D1	21090130	Silicon U05B	·		SPEAKER
D3~15	21090100	* 10D1	SP1	76000017	4Ω 3W SA-77KY
D2	21090114	Bridge Rectifier Module S15VB10		10000011	
	21030144	Bridge Rectifict Module 515/510			
					RELAY
		RESISTOR	RL1	70000005	AE-3171-42
D10	40142690	$\frac{\text{RESISTOR}}{\text{Carbon Film}} \frac{\frac{1}{4} \text{W VJ}}{68\Omega}$	RL2	70000031	BR211D012M
R10	40143680				
R9,11	40143121	<i>* * * *</i> 120Ω	PB-1829	60418290	RL2, Support Board
R2	42124100	Composition ½W GK10Ω Section 1/2 W GK10Ω			
R13	42124270	<u>* * * * 27Ω</u>			
R1	42124101	* * * * 100Ω			
R12,14	42124181	· · · · · 180Ω			RELAY SOCKET
R4,5	42124102	* * * 1KΩ	RLS	69000004	AE-3860
R8	42144223	<i>* * ¹</i> / ₄ W * 22KΩ			
R7	42144274	<i>* * * *</i> 270KΩ			
					SWITCH
			S1	61000531	Channel SRN1026N
		POTENTIOMETER	S2,4	64000520	Band SRN2064N
VR1	49800110	DM10A041A 10KΩC/10KΩA	S3	61000533	Mode SRN4086N
VR2	49800111	DM10A041A 10KΩB/100KΩB	S5	64000200	Power SP-2022
VR3	49900098	DM10A041 5KΩB/10KΩΛ			
VR4	49800112	DM11A5M1112 10KΩB/10KΩA			
VR5	49900100	EVH, BOAS25B54 50KΩB			
	-				PLUG
			P1	68130002	5047-13
			P2	68100012	5047-10
		CAPACITOR	P3	67040002	SI 5908
C14	31829010	Ceramic Disc 50WV SL 1PF			
C1,2	30240472	* * 1.4KV 0.0047μF		-	
C15~19,23~25	30820103	∞ ∞ 50WV 0.01µF			
$\frac{C13}{C6}$ -13 $\frac{C13}{C6}$	30820473	0.047μ F			RECEPTACLE
C20~22	35220475	Electrolytic $16WVT 4.7\mu F$	J1	67040004	POWER QMS-AB4M
C20~22 C26	35220476	* 10WV * 100μF	J2	68050003	TONE IN CS-250
	34120107	³ 16WV * 100μF * 16WV * 220μF	J <u>3</u>	68020002	KEY SG-7615
C5 C4	34320227	[*] 16WV * 220μF * R 2200μF	J3 J4	68020002	EXT SP SG-8050
			· · · · · · · · · · · · · · · · · · ·	68020012	MIC FM-144S
C3	34529001	* 35WV * 6800µF	.J5	68040003	PHONE SG-8018
			J6		REMOTE CN-7017J
			J7~10,14	68020001	
	0000000		J 11	68090001	BOOSTER SB-7702
TC1	39000005	ECV-1ZW 50×32 50PF	J12 (with wire)	68060018	MEMORY #240087
		MICRO INDUCTOR			MULTI JACK
L1,2,3	53020013	LA104N 151K 150µ H	MJ1~6,9,10,11	68180003	121S-18B-105 18P
· · · · · · ·			MJ7,8,12	68360001	22D-36B-205 36P
		AF CHOKE	1	-	
	55003001	SN8S-500		_	FUSE
CH1			4		
CH1 CH2	50000010	50-12 # 230012	F1	73000003	$3\Lambda (100V \sim 117V)$
CH1 CH2	50000010	50-12 # 230012	F1	73000003	3A (100V~117V) 2A (200V~234V)

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Q103Q280019FETZSK19GRSymbol NumberR2:8R2:BTo DescriptionQ1022380510~3SK594PI-168460185404Printed Circuit HomomenQ101.1042380659^3SK5970.185404PI-C.BVit ComponenQ1052231814TransistorZSC1815YPI-C.B10FETTSSN570Q105231814TransistorZSC1815YQ2042500152IC IIC IIC Q105100GermaniumIS1007Q2042500152IC IIC 2SK197D122100070GermaniumIS1007Q2052205641Transistor2SA2D101.103.104.1062109013VaristorIS2209Q207.008.210231065C2SC1D101.103.104.1062109013VaristorIS2209Q207.008.210231065CZSC1D101.103.104.1062109013VaristorIS2209Q207.020.216.217.222100818Germanium1S1007K101MONOLITHIC FILTERP201.0202109013VaristorWYYSC1SC1YYYK101MONOLITHIC FILTERR209.210.216.217.2221014301CYYYYSC1SC1YYYYSC1SC1YYYYSC1SC1YYYYYSC1SC1YYYYSC1SC1YYYYYY<	# 220150	·	74	K1Z-40	54140740	1106		······		
Q1032280019FETZSK19GRSymbol NumberR2:Bar Construct LandDescriptionQ10223805103KS47PH-16846/048400Printed Circuit LandQ101.10423800543KS470.18540APH-C.B. with componenQ10522318154Transistor-SKS197PC.B. with componenQ10522318154Transistor-Q2042500152IC~PC.C.B. with componenQ106CQ2042500152IC~PC.C.B.D10CCQ2012280193PET-2SK19D122100070GermaniumIS1007Q2092205641Transistor2SA2D101.03.104.1062102909VaristorIS2209Q207.038,210221814Transistor2SA2D101.03.104.1062102909VaristorIS2209Q207.038,210221814Germanium1S1007D102.10721090138VaristorIS2209Q207.020,210218168Germanium1S1007K101700003ILCA110X2A2#21011PD0.02C21090138Carloon Film54WK110700003ILCA110X2A2#21011PCPESISTOFR21.229.230.240914360Germanium1S1007R123.1244014305Garloon Film54WVJ<1000			نكفو		CCR			EET & TRANCLOS		
Q1022380030°°35K3PB-185460418540Optione Currents on the constraint of the constraint		intica				Symbol Number			22200105	()102
Q101,104 Z380594 * JSK59Y Q108 Q2318154 Transistor ZSC18157 C P.C.B with component Q105 22318154 Transistor ZSC18157 C IC FET & TARNSISTO Q106 22300195 FET 22500152 IC #TARNSISTO ZSC18157 Q201-203 2380594 * ZSC18157 D105 2100070 Germanium IS1007 Q206 22106641 Transistor ZSC17 D105 21090142 SS1icon MC301 Q209 2231005 * 2SC1 D105 21090142 SS1icon MC301 Q209 22318154 * 2SC1 D105 Varistor MC301 Q209 22318154 * 2SC1 D107 21090138 Varistor MV103 Cernanium IS18 * SV1001 R201,0216,217,222 Q101880 Cernanium IS18 D1005 MONOLITHIC FILTER R201,0216,217,222 Q1014800 *				Drint-J						
Q108 22318154 Transistor 2SC18157 IC IC FET & TRANSISTOR IC 2230054 IC \$	e					1.15-1004		· · · ·		
Image: Normal State	د 	mponents	with CO	г.с.в	010040AZ					
Image: state		STOP	TRANG	IC FET %			2301813 1	1 ransistor	22318154	4109
Image: bit state		$\frac{\mu PC1037}{\mu PC1037}$	TRAIN		25000152	()204				
Image: biologe Q201-203 2380594 * 35863 D112 2109070 Germanium 151007 Q206 2210641 Transistor 25A8 D105 21090142 Silicon MC301 Q209 2231005 25C D101.103.104.106 21090138 Variator MV103 2200010 2218164 25C D102.107 Z009138 Variator MV103 151007 1000 2001080 Germanium 15107 D102.107 Cambon Differ MV103 1020.202 2100188 Variator MV103 Table MonOLITHIC FILTER 10201.022 #210111 RESISTOR		2SK19GE								
D112 D1000 Germanium 151007 12064 200005 2105031 Transistor 2504 D105 21090142 Silicon MC301 Q209 22310005 ~ 25C1 D101.103.104.106 2102209 Varactor 152209 Q207.208.210 22318154 ~ 25C1 D102.107 21090138 Varistor MU103 DIODE D102.107 2109018 Varistor MU103 DIODE MU103 Componential MONOLITHIC FILTER D201.202 21090138 Carbon Film MU MONOLITHIC FILTER R209.210.216.217.222 40143560 Carbon Film ½W MI14 M143101 ~ ~ T R207.216.217.222 40143520 ~ ~ R123.124 40143560 Carbon Film ½W VJ 560 R214.249.230.233.244 40143122 ~ ~ ~ R114 40143101 ~ ~ TJ<10001							,	DIODE		
D105 21090142 Silicon MC301 Q209 2231005 \$		2SA564A				+	1\$1007		91010070	D119
D101,103,104,106 2102209 Variator 152209 Q207,208,210 22318154 · · 2SC1 D102,107 21090138 Varistor MV103 C D - - SC1 - SC1 - SC1 - SC1 - SC1 SC1 - SC1 SC1 - SC1 SC1 </td <td></td> <td>2SA304A 2SC1000</td> <td>stor</td> <td></td> <td></td> <td>ł</td> <td></td> <td>· · · · · · · · · · · · · · · · · · ·</td> <td></td> <td></td>		2SA304A 2SC1000	stor			ł		· · · · · · · · · · · · · · · · · · ·		
D102,107 21090138 Varistor MV103 MV103 DODE Image: Control of the contro										
Indication Indication Indication Didde Didde Image: Imag	101	2301013		·	22310134					
Image: def matrix D203,204 21001880 Germanium 1518 MONOLITHIC FILTER D201,202 2109138 Varistor MV XF101 71000033 HICM10N2A2 #210111 RESISTOR RESISTOR RESISTOR Varistor MV XF101 71000033 HICM10N2A2 #210111 R209,210,216,217,222 40143560 Carbon Film ½W XF101 RESISTOR R209,210,216,217,222 40143560 Carbon Film ½W ½W XJ 56Ω R21 40143010 40 40 4014301 40 4014301 40 40 4014301 40 40 4014301 40 40 4014302 40 <td< td=""><td>· · · · ·</td><td></td><td></td><td>DIODE</td><td></td><td></td><td>WI V 105</td><td>varistor</td><td>21090136</td><td>1)102,107</td></td<>	· · · · ·			DIODE			WI V 105	varistor	21090136	1)102,107
Image: https://image: htttps://image: https://image: https://image: htttps://image: htt	FM	1S188FN	ium		21001880	D203 204				
Image: Monol_ITHIC_FIL_TEX Image: Monol_ITHIC_FIL_TEX Image: Monol_ITHIC_FIL_TEX Image: Monol_ITHIC_FIL_TEX Restart		MV-103		- · · · ·			<u> </u>			•
XF101 71000033 HCM10N2A2 # 210111 Recurrence					21000100		TFR	MONOLITHIC FU		
Image: constraint of the state of the s				RESISTOR					71000033	XF101
Image: https://image: htttps://image: https://image: htttps://image: htttps://image: ht	V.I 56Ω	1/4W VJ			40143560	R209 210 216 217 222	# 210111	HOMITONZAZ	71000033	
RESISTOR R25,248 40143101 0 0 0 R123,124 40143560 Carbon Film ½W VJ 56Ω R221 40143221 0 0 0 R114 41143101 0 0 0 TJ 100Ω R207,214,229,230,233,244 40143102 0	× 68Ω					• · · · · · · · · · · · · · · · · · · ·	· · · · · · · · · · · · · · · · · · ·			
R123,124 40143560 Carbon Film ½W VJ 56Ω R221 40143221 ~ ~ ~ R114 41143101 ^ ^ ^ TJ 100Ω R207,214,229,230,233,244 40143102 ~	× 100Ω							PESISTOP		
R114 41143101 • • TJ 100Ω R207,214,229,230,233,244 40143102 • • • R116 40143101 • • VJ 100Ω R241 40143122 •	× 220Ω			· · · ·			1/W VI 560		40142560	D192 194
R116 40143101 * * VJ 100Ω R241 40143122 * * * R112 40143221 * * * 220Ω R231 40143152 * * * * R109 41143102 * * * TJ IKΩ R250 40143222 * * * * R105,118,122 40143102 * * * VJ IKΩ R250 40143322 * * * R105,118,122 40143102 * * * 4.7KΩ R24,236,240 40143323 * * * R119 4014322 * * * 4.7KΩ R24,236,240 40143472 * <t< td=""><td>× 1KΩ</td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td></td><td>· · ·</td></t<>	× 1KΩ									· · ·
R112 40143221 • • • • • • • 220Ω R231 40143152 • • • • • • • • • • • • • • • • • • •	× 1.2KΩ									
R109 41143102 · · · · · · · · · · · · · · · · · · ·	 1.2KΩ 4.5KΩ 									
R105,118,122 40143102 • • V.J 1KΩ R224,236,240 40143322 • • • R128 40143472 • • • 4.7KΩ R249 40143472 •	× 1.3K12 × 2.2KΩ									
R128 40143472 • • 4.7KΩ R249 40143472 • • • R119 40143822 • • • 8.2KΩ R227,247 40143562 • <td> 2.2KΩ 3.3KΩ </td> <td></td> <td></td> <td>· · · · ·</td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>	 2.2KΩ 3.3KΩ 			· · · · ·						
R119 40143822	 3.3KΩ 4.7KΩ 					· · · · · · · · · · · · · · · · · · ·				
R113,125,126,127 40143103 ⁰ ⁰ IOKΩ R234 40143822 ⁰	 4.7KΩ 5.6KΩ 									-
R103,120 40143223 · · · · · · · · · · · · · · · · · · ·	 3.0KΩ 8.2KΩ 									
R108,111 40143473 ····································	 3.2Ku 3.2Ku 4.10KΩ 									
R125 40143683 • • • • 68KΩ R218 40143223 •<	 10KΩ 15KΩ 									·
R101,106,107,110 41143104 ^o ^o TJ 100KΩ R243,246 40143273 ^o R104 </td <td> 22KΩ </td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td> <td></td>	 22KΩ 									
R102,115,117,121 40143104 ^o ^o ^v	× 27KΩ									
R104 40143225 4 4 2.2MΩ R237,242 40143393 4 4 R20 40143563 4	 39KΩ 									
R220 40143563 * * * CAPACITOR R202,212,219 40143104 * * *	 33KΩ 47KΩ 			· · · · · · · · · · · · · · · · · · ·						
CAPACITOR R202,212,219 40143104 * * *	 47 KΩ 56 KΩ 								40143223	1104
	 30Ku2 30Ku2 30Ku2 									
C100 [21220050] Coronic Disc. 50WV SL 0 5DF [R232] [40142184] 4 4 4	 100KΩ 180KΩ 				40143104 40143184	R202,212,219 R232	50WV SL 0.5PF	Ceramic Disc	21020050	(100
	 780KΩ 220KΩ 									
	 220KM 220KM MΩ 	·· · ·								
	 1.5MΩ 									
	1. 01/11/2		· · · · · · · · · · · · · · · · · · ·		40143133	1/200		· · · · · · · · · · · · · · · · · · ·	-	
									-	
C141 31820040									+	

TIDOOO		POTENTIOMETER			111004		CRYSTAL F		2		
VR202	49906103	EVL-SOAA 00B14		10KΩB	XF301	71000034	XF10.8H				210112
VR201	49906503			50KΩB	XF302 (OPTION)	71000035	XF10.8H	С			210113
VR203	40906504			500KΩB							
		· · · · · · · · · · · · · · · · · · ·									
					D205 207 211 210	41140101	RESISTOR	211.	1/10	ΤI	1000
C201,207,212,229	31829100	CAPACITOR Ceramic Disc 50W	WVSL	INDE	R305,307,311,312 318,321,326,327	41143101	Carbon I	i i îm	⅓₩	13	100Ω
C216	31829180		w w	18PF	R302,310,325	40143101		"	"	VJ	100Ω
C231,232	31829101	· · · ·	<i>"</i> "	100PF	R301,303,304,306,308	40143102	~	"	4	4	1ΚΩ
C249,250	31829221	<i>"</i> "	"	220PF	R309,319,320,322~324						
C204,208,238	30820102	<i>"</i> "	" "	0.001µF	R317	40143222		"	"	4	2.2KΩ
C202	38820103	» »	"	0.01µF	R328,329	40143103	"	"	"	4	10KΩ
		(RD204YM 10	03Z)		R316	41143473	"	4	"	ŤJ	47ΚΩ
C203,205,206,209,210	30820103	» »	"	0.01µF	R315	40143473	*	"	"	VJ	47ΚΩ
211,213,214,215,217					R313,314	40143104	"	"	4	"	100KΩ
218,219,221,223,224					· _ · _ ·			<u>-</u>			
226~228,234,236,247											
C230	30820473		<i>"</i>	0.047µF			CADACITOD				
C244	36825102		". ".	0.001µF	C220	21920000	CAPACITOR Ceramic		5014/1	Cu	0PF
C243 C248	36825472 36825103		4 1)	0.0047µF 0.01µF	C320 C311	31820090 31820100	Ceramic	Disc	50WV	<u>сн</u>	9PF 10PF
C233	36825103		<i>"</i>	0.01μ F	C314,316	31829470	, ,				47PF
C233	36825223	Tantalum 16V		2.2µF	C314,316	30820102	*	"		56	0.001µ
C239,241,245	34820105		WV T	1µF	C301,305~309,312,319	30820102	"	"	"		0.01µF
C220,222,237,240	34220106		WVT	10µ F	323~326,330,331	000000000					0.01/-1
C225,242,246	34120476		WV *	47µF	C302~304,310,313,315	30820473		*	"		0,047µ
					C318, 321, 322, 327~329 332, 333						
-											
		MICRO INDUCTOR									
L201,202	53020009	FL		1mH							
L203	53020012	FL	,4H	1.2µH	L 201 200	52020012	MICRO IND	UCTOF	·		15011
					L301~306	53020013	FL-5H				150µH
		TRANSFORMER									
T201,202	54140730	R12-4073	±	\$220149			TRANSFORM	/ER			
T203	54140740	R12-4074		\$220150	T301	54140730	R12-4073			+	220149
		FERRITE BEADS					PIN TERMI				
FB	56000024	RI 3×3×1				91100011	M S-6012				
						A		_			
					Symbol Number	Parts Number	DIN	Descr	<u>.</u>		
		LER UNIT			PB-1764A-3380	60417641	Printed				
Symbol Number	Parts Number	Description				017641BZ	Р.С.В т	vith co	mponent	ιs	
PB-1855	60418550 018550AZ	Printed Circuit Boa P.C.B with compon									
	01000047	I.O.D with compon-					IC, FET &	TRANS	SISTOR	2	
		· · · · · · · · · · · · · · · · · · ·			Q415	25000111	IC		MC14		}
					Q416,417	22800304	FET		2SK3		
		FET & TRANSISTOR			Q412	22105641	Transist	or	2SA5		
Q301,302,304	22800195		K19GR		Q404	22106950	*		2SA6		· · ·
Q303	22318154		C1815 Y		Q406	22205290	~ ~		2SB5		
······					Q402,407,408,414	22303724	"		2SC3	72 Y	
					Q409,410,413,418	22303730	"		2SC3	73	
					Q403	22307114	*		2SC7	11D	
		DIODE			Q411	22307354	*		2SC7	35 Y	
D301~306	21010070	Germanium 1S	1007		Q405	22403590	*		2SD3	59	

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				I	(1107		T11	1 CHEVE TE	10017
		DIODE	101555		C407	34220107	Electrolytic //	16WVT	100µ F 220µ F
1)401~404	21015550	Silicon	1S1555		C408,412	34220227			220μ Γ
1)405	29090013	Varistor	MV-5W						
		RESISTOR							
R416	40143100	Carbon Film	⅓W VJ	10Ω		FM			
R456	40143680	4 H	~ ~	68Ω	Symbol Number	Parts Number		ription	
R414,457	40143101	4 4	* *	100Ω	PB-1856	60418560	Printed Circui		
R420	40143121	4 4	" "	120Ω		018560AZ	P.C.B with co	omponents	
R417	40143221	* *	" "	220Ω					
R425,449,454	40143471	<i>"</i> "	<i>4</i> 4	470Ω					
R406, 408, 428, 430, 434, 441	40143102	" "	" "	1ΚΩ					
R412,413	40143152		<i>n n</i>	1.5KΩ			IC, FET & TRAN	SISTOR	
R424,450	40143222	4 4	~ ~ <i>~</i>	2.2KΩ	Q501	25000134	IC	TA7063P	
R415	40143332	4 4	" "	3.3KΩ	Q503	25000111	"	MC14011H	3
R440,443,445,446,448,455	40143472		11 11	4.7KΩ	Q511	25000118	*	μ PC577H	
R429	40143562	" "	* *	5.6KΩ	Q505,516	23800594	FET	3SK59Y	
R409	40143682	" "	<i>4 4</i>	6.8KΩ	Q502,504,506~510	22318154	Transistor	2SC1815Y	. –
R421,427,436,438	40143103	* *	* *	10KΩ	$512{\sim}515,517,{\sim}519$				
439,444,452,453									
R422,442	40143223	* *	" "	22KΩ					
R447	40143333	" "	<i>n n</i>	33KΩ					
R426	40143393	" "	· · ·	39ΚΩ			DIODE		
R404,410	40143473		4 4	47KΩ	D502~506,508~510	21001880	Germanium	1S188FM	
R435	40143563	» »		56KΩ	D501,507	21015550	Silicon	1S1555	
R423	40143683	11 11	4 4	68KΩ					
R411,437	40143104	" "	·/ ·/	100KΩ					
R405,451	40143224	4 4	11 11	220ΚΩ					
R458	41143224		∽ TJ	220KΩ			THERMISTOR		
R431,432	40143105	4 4		1ΜΩ	TH501	29090001	SDT-250		
R418,419	40124029	Wire Wound	1/2 W *						
R433	40124029	Carbon Composi							
11400	42144555	Carbon Composi							
							CRYSTAL		
						71800118	HC-18/U 11.2	65MHz	+ 010110
					X501				+ 210110
		POTENTIOMETER			X501		110 10/ 0 11.2		\$210110
VD404	40006202		200	2KOB	X501				+ 210110
VR404	49906202	EVL-SOAA 00F		2KΩB	X501				+ 210110
VR403	49906103	EVL-SOAA 00F EVL-SOAA 00F	314	10KΩB	X501				+ 210110
VR403 VR402	49906103 49907053	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F	314 354	10ΚΩΒ 50ΚΩΒ			CERAMIC FILTE		+ 210110
VR403 VR402 VR405	49906103 49907053 49906503	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-SOAA 00F	314 354 354	10ΚΩΒ 50ΚΩΒ 50ΚΩΒ	CF501	71200006	CERAMIC FILTE SFE-10.7MS		
VR403 VR402	49906103 49907053	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F	314 354 354	10ΚΩΒ 50ΚΩΒ	CF501 CF502,503	71200006 71200016	CERAMIC FILTE SFE-10.7MS LFB-15		+ 210110
VR403 VR402 VR405	49906103 49907053 49906503	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-SOAA 00F	314 354 354	10ΚΩΒ 50ΚΩΒ 50ΚΩΒ	CF501	71200006	CERAMIC FILTE SFE-10.7MS		+ 210110
VR403 VR402 VR405	49906103 49907053 49906503	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-SOAA 00F	314 354 354	10ΚΩΒ 50ΚΩΒ 50ΚΩΒ	CF501 CF502,503	71200006 71200016	CERAMIC FILTE SFE-10.7MS LFB-15		+ 210110
VR403 VR402 VR405	49906103 49907053 49906503	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-SOAA 00F EVL-VOAA 00F	314 354 354 355	10ΚΩΒ 50ΚΩΒ 50ΚΩΒ	CF501 CF502,503	71200006 71200016	CERAMIC FILTE SFE-10.7MS LFB-15		+ 210110
VR403 VR402 VR405 VR401	49906103 49907053 49906503 49907504	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-SOAA 00F EVL-VOAA 00F CAPACITOR	314 354 354 355	10ΚΩΒ 50ΚΩΒ 50ΚΩΒ 500ΚΩΒ	CF501 CF502,503	71200006 71200016	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4	R	+ 210110
VR403 VR402 VR405 VR401 C438	49906103 49907053 49906503 49907504 	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-SOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc	314 354 355 355 50WV SL	10KΩB 50KΩB 50KΩB 500KΩB	CF501 CF502,503 CF504	71200006 71200016 71200022	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR	R	+ 210110
VR403 VR402 VR405 VR401 C438 C404	49906103 49907053 49906503 49907504 31829151 31829251	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc	314 354 355 355 50WV SL	10KΩB 50KΩB 50KΩB 500KΩB 	CF501 CF502,503	71200006 71200016	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4	R	+ 210110
VR403 VR402 VR405 VR401 C438 C404 C434	49906103 49907053 49906503 49907504 31829151 31829221 31829271	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-SOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc	314 354 355 50WV SI.	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF	CF501 CF502,503 CF504	71200006 71200016 71200022	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR	R	
VR403 VR402 VR405 VR401 C438 C404 C434 C409	49906103 49907053 49906503 49907504 31829151 31829221 31829221 31829271 31829331	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % %	314 354 355 355 50WV SL	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF 330PF	CF501 CF502,503 CF504	71200006 71200016 71200022	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR	R	+ 210110
VR403 VR402 VR405 VR401 C438 C404 C434	49906103 49907053 49906503 49907504 31829151 31829221 31829271	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % %	314 354 355 50WV SI.	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF 330PF 0.001µF	CF501 CF502,503 CF504	71200006 71200016 71200022	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4	R	+ 210110
VR403 VR402 VR405 VR401 C438 C404 C434 C409	49906103 49907053 49906503 49907504 31829151 31829221 31829221 31829271 31829331	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % %	314 354 354 355 50WV S1 % % %	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF 330PF	CF501 CF502,503 CF504	71200006 71200016 71200022 70900001	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR	R	
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427	49906103 49907053 49906503 49907504 31829151 31829221 31829221 31829221 31829231 30820102	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc	314 354 354 355 50WV SI % % %	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF 330PF 0.001µF	CF501 CF502,503 CF504	71200006 71200016 71200022	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film	R IMINATOR	56Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401	49906103 49907053 49906503 49907504 31829151 31829221 31829271 31829271 31829331 30820102 30820473	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc	314 354 354 355 50WV SI % % %	10KΩB 50KΩB 50KΩB 500KΩB 1500FF 220PF 270PF 330PF 0.001μF 0.047μF	CF501 CF502,503 CF504 CD501	71200006 71200016 71200022 70900001	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR	R IMINATOR	56Ω 100Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401 C423,436,437	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829331 30820102 30820473 36825103	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 354 355 50WV SI % % %	10KΩB 50KΩB 50KΩB 500KΩB 1500PF 22012F 2702F 2702F 3302F 0.001μF 0.047μF	CF501 CF502,503 CF504 CD501 R547	71200006 71200016 71200022 70900001 40143560	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film	R IMINATOR	56Ω 100Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401 C423,436,437 C431,432,433	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829331 30820102 30820473 36825103 36825223	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI. % % % %	10KΩB 50KΩB 50KΩB 500KΩB 200F 220PF 270PF 330PF 0.001μF 0.047μF 0.01μF 0.02μF	CF501 CF502,503 CF504 CD501 R547 R542,581	71200006 71200016 71200022 70900001 40143560 41143101	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film 4 4	R IMINATOR	56Ω 100Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401 C423,436,437 C431,432,433 C414,417,440	49906103 49907053 49907053 49907504 31829151 3182921 3182921 31829271 31829271 3182931 30820102 30820473 36825103 36825223 36825473	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI. % % % % %	10KΩB 50KΩB 50KΩB 500KΩB 200F 220PF 270PF 330PF 0.001μF 0.047μF 0.02μF 0.047μF	CF501 CF502,503 CF504 CF504 CD501 R547 R547 R532,581 R521,538,572,576	71200006 71200016 71200022 70900001 70900001 40143560 41143101 40143101	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film 2 2 2 2 2 2 2 2	R IMINATOR ¼W VJ % TV % VJ	56Ω 100Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401 C423,436,437 C431,432,433 C414,417,440 C422	49906103 49907053 49907053 49907504 31829151 3182921 3182921 31829271 31829271 3182931 30820102 30820473 36825103 36825223 36825473 36526334	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI. ~ ~ ~ ~ ~ ~ ~ ~ 35WV	10KΩB 50KΩB 50KΩB 500KΩB 200F 220PF 270PF 330PF 0.001μF 0.001μF 0.02μF 0.02μF 0.047μF 0.33μF	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571	71200006 71200016 71200022 70900001 	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film * * * * *	R IMINATOR 4W VJ * TV * VJ * VJ	56Ω 100Ω 150Ω
VR403 VR402 VR405 VR401 C438 C404 C434 C409 C427 C401 C423,436,437 C431,432,433 C414,417,440 C422 C425	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829221 31829221 31829221 31829221 31829231 30820102 30820473 36825103 36825233 36825473 36526334 36526105	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI ~ ~ ~ ~ ~ ~ ~ ~ ~ 35WV ~	10KΩB 50KΩB 50KΩB 500KΩB 150PF 220PF 270PF 330PF 0.001μF 0.02μF 0.02μF 0.02μF 0.33μF 1μF	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571 R523,543	71200006 71200016 71200022 70900001 40143560 41143101 40143101 40143151 40143221	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film * * * *	R IMINATOR 1/4W VJ * TV * VJ * VJ * 7	56Ω 100Ω 100Ω 150Ω 220Ω
VR403 VR402 VR405 VR401 C438 C404 C438 C404 C434 C409 C427 C401 C422,436,437 C431,432,433 C414,417,440 C422 C425 C424 C403,406,415,419,428,430	49906103 49907053 49907053 49907504 31829151 31829221 36825473 36825473 368256334 36526233 36526235 34820105	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI 20WV SI 20WV SI 20WV 20 20 20 20 20 20 20 20 20 20 20 20 20	10KΩB 50KΩB 50KΩB 500KΩB 500KΩB 150PF 220PF 270PF 330PF 0.001μ F 0.047μ F 0.02μ F 0.02μ F 0.047μ F 0.32μ F 1μ F 2.2μ F	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571 R523,543 R508	71200006 71200016 71200022 70900001 40143560 41143101 40143101 40143151 40143221 40143331	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film * * * * * *	R IMINATOR 1/4W VJ 0 TV 0 VJ 0 VJ 0 VJ 0 VJ 0 VJ 0 VJ	56Ω 100Ω 100Ω 150Ω 220Ω 330Ω
VR403 VR402 VR405 VR401 C438 C404 C438 C404 C434 C409 C427 C401 C427 C401 C423,436,437 C431,432,433 C414,417,440 C422 C425 C424 C425 C424 C403,406,415,419,428,430 C435	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829271 31829331 30820102 30820473 36825103 36825223 36825473 36526334 36526105 36526225 34820105 34220475	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 355 50WV SI 20WV SI 20WV SI 20WV SI 20 20 20 20 20 20 20 20 20 20 20 20 20	10KΩB 50KΩB 50KΩB 500KΩB 500KΩB 150PF 220PF 220PF 270PF 330PF 0.001μ F 0.047μ F 0.02μ F 0.02μ F 0.33μ F 1μ F 2.2μ F 1μ F 4.7μ F	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571 R523,543 R508 R507,528	71200006 71200016 71200022 70900001 40143560 41143101 40143151 40143221 40143331 40143391	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film * * * * * * * *	R IMINATOR 1/4 W VJ 0 TV 0 VJ 0 VJ 0 VJ 0 VJ 0 0 0 0 0 0 0 0 0 0 0 0	56Ω 100Ω 150Ω 220Ω 330Ω 390Ω
VR403 VR402 VR405 VR401 C438 C404 C438 C404 C434 C409 C427 C401 C427 C401 C423,436,437 C431,432,433 C414,417,440 C422 C425 C424 C425 C424 C403,406,415,419,428,430 C435 C416,418,421,426,429	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829221 31829221 31829221 31829221 31829221 31829221 31829221 31829221 30820473 36825103 36825223 36825473 36526334 36526105 34220475 34220106	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % % % % % % % % % % % % %	314 354 354 355 50WV SI ~ ~ ~ ~ 355WV ~ ~ 35WV ~ ~ 35WV ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~ ~	10KΩB 50KΩB 50KΩB 500KΩB 500KΩB 150PF 220PF 270PF 270PF 330PF 0.001μ F 0.001μ F 0.02μ F 0.047μ F 0.02μ F 1μ F 2.2μ F 1μ F 4.7μ F 10μ F	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571 R523,543 R508 R507,528 R500,546,552 R501	71200006 71200016 71200022 70900001 40143560 41143101 40143101 40143221 40143221 40143331 40143391 40143471 41143102	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	R IMINATOR 4/W VJ 6 TV 9 VJ 6 TV 9 VJ 6 7 7 7 6 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7	56Ω 100Ω 150Ω 220Ω 330Ω 390Ω 470Ω
VR403 VR402 VR405 VR401 C438 C404 C438 C404 C434 C409 C427 C401 C427 C401 C423,436,437 C431,432,433 C414,417,440 C422 C425 C424 C425 C424 C403,406,415,419,428,430 C435	49906103 49907053 49907053 49907504 31829151 31829221 31829221 31829271 31829331 30820102 30820473 36825103 36825223 36825473 36526334 36526105 36526225 34820105 34220475	EVL-SOAA 00F EVL-SOAA 00F EVL-VOAA 00F EVL-VOAA 00F EVL-VOAA 00F CAPACITOR Ceramic Disc % % % % % % % Mylar % % Tantalum % % Electrolytic %	314 354 354 355 50WV SI ~ ~ ~ ~ ~ ~ ~ 35WV ~ ~ 35WV ~ ~ 50WV T 16WV ~	10KΩB 50KΩB 50KΩB 500KΩB 500KΩB 150PF 220PF 220PF 270PF 330PF 0.001μ F 0.047μ F 0.02μ F 0.02μ F 0.33μ F 1μ F 2.2μ F 1μ F 4.7μ F	CF501 CF502,503 CF504 CD501 R547 R532,581 R521,538,572,576 R518,571 R523,543 R508 R507,528 R507,528 R530,546,552	71200006 71200016 71200022 70900001 40143560 41143101 40143151 40143221 40143331 40143391 40143471	CERAMIC FILTE SFE-10.7MS LFB-15 LFB-4 CERAMIC DISCR SFD455S4 RESISTOR Carbon Film \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$ \$	R IMINATOR 4/4W VJ 2 TV 2 VJ 2 TV 2 VJ 2 X 3 X 4 X 3 X 4	56Ω 100Ω 100Ω 150Ω 220Ω 330Ω 390Ω 470Ω 1ΚΩ

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R531,536,548,566	40143222	Carbon Film	1⁄4 WV VJ	2.2KΩ	777.01		TRANSFORMER	
579,580		ļ			T501	54140730	R12-4073	# 220149
R533,559,561,565	40143332	" "	<i>" "</i>	3.3KΩ	T502	54179430	R12-7943	
R524,545	40143472		4 4	4.7ΚΩ	T503	54179350	R12-7935	
R540,549,550,562,574	40143562	* *	<i>» »</i>	5.6KΩ	T504	54179470	R12-7947	
R504,509,512,513,514	40143103	* *	4 4	10KΩ				
520,526,527,551,554								
564 R515,534,535,539,542	40143223	· · · ·		22ΚΩ	TP501,502	91100008	Wrapping Term	ínal C
553,568,573							11	
R505	40143393		" "	39KΩ				
R555	40143563	4 4	* *	56KΩ				
R516,517,544,557,558	40143104	4 4		100KΩ	· · ·			
560,567,569,577,578								
R503	40143154	" "	4 4	150KΩ		MIC	AMP UNIT	
R525	40143224		<i>n n</i>	220KΩ	Symbol Number	Parts Number	Descri	ption
R506,529,556	40143274			270KΩ	PB-1857	60418570	Printed Circuit	·
R522	40143474			470KΩ		018570AZ		
R510	40143105	" "	4 4	1MΩ				•
R510	42144335		ition ¼W					
	42144000	Compos.		0110.01012		<u> </u>		
							FET & TRANSIST	OR
					Q603	22800195	FET	2SK19GR
		POTENTIOMETER			Q609	23800401	"	3SK40M
VR503	49906103	EVL-SOAA 00		10KΩB	Q610	22310005	Transistor	2SC1000GR
VR501	49906503		B55	50KΩB	Q601,602,604~608	22318154	*	2SC1815Y
VR502	49906504		B14	500KΩB	611~613			
							-	
		CAPACITOR					DIODE	
C528	31829050	Ceramic Disc	50WV SL	. 5PF	D605~608	21010070	Germanium	1S1007
C504, 527, 556	31829200	" "	4 4	20PF	D601~604,609	21015550	Silicon	1S1555
C510,521,573	31829470	" "	4 4	47PF	612~620		i	
C522,523	31829151			150PF	D610	21090108	Varactor	1S2209
C501,502,517,538	30820102		<i>4 4</i>	0.001µF	D611	29090004	Varistor	MV103
C516,518~520,524	30820103			0.01µF				
526,552	00020100			,				
C529,530	30820473		"	0.047µF				
C531,534,536,539,546	36825102	Mylar	"	0.001µF			CRYSTAL	
547,562,566,570,576					X601	71800119	HC-18/U 10.80	85MHz #210099
C579	36825472	"	"	0.0047 <i>µ</i> F	X602	71800120	× 10.81	15MHz #210100
C512,515,537,540,553		, ,	4	0.01µF	X603	71800121		10 MHz #210101
554,558,577	00020100			0,01/.	X604	71800122	-	50 MHz #210102
C548~550,578	36825223	,	"	0.022µF		.1000122	10.00	
$C548 \sim 550, 578$ C507, 532, 533, 535, 541	36825473	,		0.022µT				
\sim 545,557,561,565	00020410			0.011/01				
$567 \sim 569, 571, 572$					· · · · · · · · · · · · · · · · · · ·		RESISTOR	
C514,564,580	36526104	Tantalum	35W V	0.1µF	R680	40143100	Carbon Film	¹ / ₄ W VJ 10Ω
C514,564,580 C513	36526104	rantatum 4	30111	$\frac{0.1\mu}{1\mu}$ F	R679	40143100		×4 \(\(\(\) \(
				1μ F 1μ F	R679	40143470	· · ·	
C503,551,582	34320105 34820225	# Electrolytic	50W V 1	1μ F 2.2μ F	R630 R605,609,610,616,618			× × 5612 × × 100Ω
C506						40143101		10012
C559,560	34320475	*	25WV «	4.7μF	634,643,654,677	40140151		4 4 1500
C505,508,525,563,574	34220106	*	16WV 🦘	10µ F	R662	40143151	<i>"</i> "	
575,581	04100-00		10107	17 5	R604,608,611,612,621	40143221	* *	» « 220Ω
C509,511	34120476	"	10WV 🧳	47μ F	655,669	107.10		
		L			R619,622,629,639,646	40143471	* *	« « 470Ω
					660,670	101 12-11		
		ļ			R663	40143561		~ ~ 560Ω
		MICRO INDUCTOR	२		R601	40143681	* *	~ ~ 680Ω
L501,502	53020001	FL-5H-102J		1mH	R615,617,620,633,642	40143102	<i>y y</i>	» « 1KΩ
					647			
					R656	40143182	<i>0</i> 0	🍬 🍬 1.8KΩ
					R653,676	40143222 40143272	<i>4 4</i>	 <!--</td-->

	Г	1 02					
40143332	Carbon Film	$\frac{1}{4}W = V$				INDUCTOR	1001 1 11
40143472	" "	" "				FL-5H	102J 1mH
40143562	<u> </u>	4 4		1.604	55003256		# 220319
40143103	4 4	4 4	- 10KΩ				
40143123	<u> </u>	· · ·					
40143153	11 11	" "					# 000140
40143183	4 4	" "	- <u>18</u> ΚΩ	T601~603	54140730	R12-4073	# 220149
40143223	4 4	<i>n n</i>	22ΚΩ				
40143333	4 4	" "	- 33KΩ				
40143473	4 4	* *	· 47KΩ				
40143683	4 4	<i>n</i> 4	· 68KΩ				
40143823	4 4	4 4	- 82KΩ				
40143104	4 4	4 4	- 100KΩ				
40143184	1, 1,	4 4	180KΩ	Symbol Number	Parts Number		ription
40143224	4 4	4 6	220KΩ				
40143274	4 4	4 6	270KΩ		018580AZ	P.C.B with o	omponents
40143394	4 4	4 1	× 390KΩ				
	POTENTIOMETER			Q701	25000101	IC	MC-1496G
49800113	PN822H 101V		100ΩB	Q702	23800510	FET	3SK51Y
49906502	EVL-SOAA 00J	353	10KΩB	Q704	22307300	Transistor	2SC730
	/ 00I	B14	5ΚΩΒ	Q705	22307842	"	2SC784R
				Q703	22320530	"	2SC2053
				Q707	22318154	11	2SC1815Y
				Q706	22390001		MPSA13
	CAPACITOR						
31820050		50WV	CH: 5PF				
						DIODE	
	· · ·			D701 708~711	21015550	Silicon	1S1555
					21022090	Varactor	1S2209
						Zener	WZ034
							<u>.</u>
						RESISTOR	
		·		R725 733	40143100		¹ / ₄ W VJ 10Ω
							~ ~ 56Ω
30820103			0.01#1				* * 100Ω
					40143101		
				/31,/38	40143991		
				D700			* * 270Ω
			0.0000 1				· · · 470Ω
				· · · · · · · · · · · · · · · · · · ·			 « % 820Ω
+							* * 82042 * * 1KΩ
36825472							* * 1.2KC
36825103	*						× × 1.2KG
36825223	*					·	* * 2.2K4
36226106							* * 3.3K
34820105	Electrolytic	50WV	Τ 1μF	R735			
36220106	"			R717,718			« « 22KΩ
34120336	"				· · · ·		 « 39KΩ 47KΩ
34120476	"			R732			
34120107	"	"	∞ 100µ F	R711,713,715,719,721			* * 100KG
				R737	40143105		« « 1MΩ
	+			R712	40143105	5 Carbon Com	
				T	42124471	"	
				R727,730	42124475	· ~	
	TRIMMER CAPA	CITOR		R727,730 R704	42124473	<i>"</i>	* ¼W GK 1.5KG
39000007			20PF		42124473		 ½W GK 1.5KΩ
39000007			20PF	R704	42124473	<i>"</i>	୬ ¼W GK 1.5KG
	40143472 40143562 40143103 40143123 40143123 40143153 40143123 40143183 40143223 40143223 40143473 40143823 4014324 40143224 40143244 40143274 40906502 49900103 31820050 31820050 31820050 31820101 31820102 30820103 318270101 30820103 36825472 36825472	40143472 * 40143562 * 40143103 * 40143103 * 40143103 * 40143153 * 40143153 * 40143183 * 40143223 * 40143333 * 40143473 * 40143683 * 40143104 * 40143184 * 40143184 * 40143184 * 40143184 * 40143184 * 40143224 * 40143274 * 40143284 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 40143294 * 4014394 * <	40143332 Carbon Film ¼W V 40143362 0 0 0 0 40143103 0 0 0 0 40143123 0 0 0 0 40143123 0 0 0 0 40143123 0 0 0 0 40143123 0 0 0 0 40143123 0 0 0 0 40143223 0 0 0 0 40143104 0 0 0 0 40143184 0 0 0 0 0 40143184 0 0 0 0 0 0 0 0 40143224 0 <td>40143332 Carbon Film $\frac{1}{4}$W VJ 3.3KΩ 40143562 \circ \circ 4.7KΩ 40143562 \circ \circ 4.7KΩ 40143103 \circ \circ \circ 10KΩ 40143123 \circ \circ \circ 12KΩ 40143133 \circ \circ \circ 12KΩ 4014323 \circ \circ \circ 3KΩ 4014323 \circ \circ \circ 3SKΩ 4014323 \circ \circ \circ 3SKΩ 4014373 \circ \circ \circ 3SKΩ 40143823 \circ \circ \circ 3SKΩ 40143823 \circ \circ \circ $2$20KΩ 40143104 \circ \circ \circ $2$20KΩ 40143224 \circ \circ $2$20KΩ 40143394 \circ \circ $2$20KΩ 40143224 \circ \circ $2$20KΩ 40143224 \circ \circ $2$20KΩ 40143224 <th< td=""><td>40143472 \circ <</td><td></td><td>M14332 Carhon Film MW V3 3.3KΩ Local INDUCTOR 0413432 • • • 4.7KΩ 1.604 55020001 F1-5H 0413436 • • • 1.604 56003256 - 0414312 • • • 1.604 56003256 - 04143123 • • • 1.604 - - - 04143123 • • • 1.8KΩ T601 ~ 603 5140730 R12-4073 0414323 • • • 2.8KΩ - <</td></th<></td>	40143332 Carbon Film $\frac{1}{4}$ W VJ 3.3KΩ 40143562 \circ \circ 4.7 KΩ 40143562 \circ \circ 4.7 KΩ 40143103 \circ \circ \circ 10 KΩ 40143123 \circ \circ \circ 12 KΩ 40143133 \circ \circ \circ 12 KΩ 4014323 \circ \circ \circ 3 KΩ 4014323 \circ \circ \circ 3 SKΩ 4014323 \circ \circ \circ 3 SKΩ 4014373 \circ \circ \circ 3 SKΩ 40143823 \circ \circ \circ 3 SKΩ 40143823 \circ \circ \circ 2 20KΩ 40143104 \circ \circ \circ 2 20KΩ 40143224 \circ \circ 2 20KΩ 40143394 \circ \circ 2 20KΩ 40143224 \circ \circ 2 20KΩ 40143224 \circ \circ 2 20KΩ 40143224 <th< td=""><td>40143472 \circ <</td><td></td><td>M14332 Carhon Film MW V3 3.3KΩ Local INDUCTOR 0413432 • • • 4.7KΩ 1.604 55020001 F1-5H 0413436 • • • 1.604 56003256 - 0414312 • • • 1.604 56003256 - 04143123 • • • 1.604 - - - 04143123 • • • 1.8KΩ T601 ~ 603 5140730 R12-4073 0414323 • • • 2.8KΩ - <</td></th<>	40143472 \circ <		M14332 Carhon Film MW V3 3.3KΩ Local INDUCTOR 0413432 • • • 4.7KΩ 1.604 55020001 F1-5H 0413436 • • • 1.604 56003256 - 0414312 • • • 1.604 56003256 - 04143123 • • • 1.604 - - - 04143123 • • • 1.8KΩ T601 ~ 603 5140730 R12-4073 0414323 • • • 2.8KΩ - <

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Description Printed Circuit Board P.C.B with components TRANSISTOR Transistor 2SC1945D % 2SC2099 % 2SC496(O) DIODE Germanium 1S188FM
Z P.C.B with components TRANSISTOR Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium 1S188FM
TRANSISTOR Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium 1S188FM
Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium
Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium
Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium
Transistor 2SC1945D * 2SC2099 * 2SC496(O) DIODE Germanium
* 2SC2099 * 2SC496(O)
2SC496(O) DIODE Germanium 1S188FM
DIODE Germanium 1S188FM
Germanium 1S188FM
Germanium 1S188FM
Germanium 1S188FM
Germanium 1S188FM
0.11
Silicon 1S1209
″ 1S1555
″ 10D1
RESISTOR
$\frac{1}{2} \frac{1}{4} \frac{1}$
4 4 4 4 4 4
· · · · · · ικΩ
· · · · · · · · · · · · · · · · · · ·
Carbon Composition 1/4W GK47Ω
* * ¹ / ₂ W * 100
POTENTIOMETER
EVL-SOAA 00B32 300ΩH
CR19R, 2.2KC
EVL-SOAA 00B54 50KΩ
CAPACITOR
Ceramic Disc 50WV SL 1PF
* * * * 5PF
* * * * 47PF
* * * * 91 PF
* * * * 150PH
<i>* * * *</i> 0.001/
· · · · 0.01µ
(2222-662-02103)
<i>* * * 0.01µ</i>
Tantalum 16WV 10µF
Feed Thru 50WV 100P
2222-808-61809 801°F
2222-808-41121 120PF
) I

	1	INDUCTOR	C930	21000050	Ceramic Disc 50WV SL 5PF
1.801,802,804	55002969	# 220324	C930	31829050 31829200	Ceramic Disc 5000 (31, 31 P) % % % 20PF
1.801,802,804	55003262	# 220324	C932,933	31829200	* * * * 200PF
1.805	55003086	# 220130	C901~905,912~916	30820103	<i>2001 2001 2001 2001 2001</i>
•• •	55003312	# 220196	0.901 - 903, 912 - 910	30820103	0.01/41
L806	55003093			-	TRIMMER CAPACITOR
L807~811	55003313	# 220411	TC901~905	39000007	ECV-1ZW 20×40 20 PF
1.812	55003311	# 220338	1C901~905	3900007	ECV-12W 20×40 2011F
					MICRO INDUCTOR
			1.001 005	52020001	FL-5H 1mH
			1.901~905	53020001	250µH
(Faaa		TRANSFORMER	1.912	53010003	
T802	55003303	# 220413	L913	53020012	FL-4H 1.2µH
T803	55003304	# 220414AB			
T804	55003305	# 220415			CAL UNIT
			Symbol Number	Parts Number	Description
			PB-1860	60418600	Printed Circuit Board
				018600AZ	P.C.B with components
		RELAY			TRANSICTOR
RL801	70000031	BR221D012M			TRANSISTOR
			Q1002	22303724	Transistor 2SC372Y
			Q1001	22307851	
					DIODE
			DIGIO	01000000	
			D1013	21022090	Germanium 1S2209
			D1001~1006,	21015550	Silicon 1S1555
Symbol Number	Parts Number	Description	1007~1012		
PB-1750~3380	60417500	Printed Circuit Board			
	017500BZ	P.C.B with components			
					CRYSTAL
			X1001	71800123	HC-18/U 70.01MHz #210105
		TRANSISTOR	X1002	71800124	
Q901,902	22303724	2SC372Y	X1003	71800125	
			X1004	71800126	
			X1005~1008		HC-25/U (OPTION) #210109
		DIODE			· · ·
D901~905	21015550	Silicon 1S1555			
					CRYSTAL SOCKET
			XS1001~1004	69010012	HC-25/U SD0105
				<u> </u>	
		CRYSTAL			
X901~905		HC-25/U (OPTION) #210104			
					RESISTOR
			R1015,1017,1018	40143101	Carbon Film $\frac{1}{4}$ W VJ 100 Ω
			R1014	40143471	« « « 470Ω
		CRYSTAL SOCKET	R1002~1004	41143681	~ ~ ~ ΤJ 680Ω
XS901	69010009	HC-25/U S-20 6P	R1001,1005~1009	40143681	« « VJ 680Ω
			R1012,1013	40143101	* * * * 10KΩ
			R1010,1011	40143473	« « « 47KΩ
			R1016	40143823	<u> </u>
		RESISTOR			
R905,908,909	40143101	Carbon Film ¼W VJ 100Ω			
R904	40143221	« « « 220Ω			CAPACITOR
R901	40143152	« « « « 1.5KΩ	C1009	31820470	Ceramic Disc 50WV CH 47PF
R902,907,910	40143562	« « « « 5.6KΩ	C1017	31829050	* * * SL 5PF
R906	40143822	ο ο ο ο 8.2KΩ	C1011	31827050	* * * UJ 5PF
R903	40143223	» « « « 22KΩ	C1015	31827100	* * * * 10PF
· · ·			C1014	31827470	* * * * 47PF
			C1010,1013,1016,1020	30820102	<i>° ° °</i> 0.001µ ⊦
			C1001~1004,1005~1008	30820103	<i>ν ν ν</i> 0.01μ F
		CAPACITOR	1012,1018]	}
			• · · · · ·	• • • • • • • • • • • • • • • • • • • •	
C917~921	31820300	Ceramic Disc 50WV CH 30PF	C1019	30820473	« « « 0.047μ Η
C917~921 C929	31820300 31820101	Ceramic Disc 50WV CH 30PF	C1019	30820473	<i>~ ~ ~</i> 0.047μ Η

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		INDUCTOR			MICRO INDUCTOR		MICRO INDUC	TOR		
L1001~1008	55003306		#	220417	L1101	53020012	FL-4H 1R	2M		1.2µH
L1009	53020035	Micro Inductor	FL-4H1RC	ΟM 1μ Η						
L1010	53010004	"	FL-5H 221	1K 220µH					·	
L1012	53010002	"	× 220	0K 22µH					-	
L1011	55003307		#	220418			TRANSFORME	R		
					T1101~1104	55003298				# 220408
			_							
							FERRITE BEA	DS		
		MIX UNIT			FB	56000024	RI 3×32	×1		
Symbol Number	Parts Number	Descri	•							
PB-1861	60418610	Printed Circuit								
	018610AZ	P.C.B with con	nponents							
							BURST UNI	т		
		IC & FET			Symbol Number	Parts Number		scription		
Q1101	25000101	IC	MC1496G		PB-1862	60418620	Printed Cir	cuit Boar	d	
Q1102	23800594	FET	3SK59Y			018620AZ	P.C.B with	componei	nts	
				· · · · ·						
· · · · · · · · · · · · · · · · · · ·										
		DIODE					IC & TRANSIS	STOR		
D1101~1104	21022090	Varactor	1S2209		Q1204,1207	25000114	IC	MC1	4011	В
					Q1206	25000155	*	MSM		
					Q1201	22310005	Transistor	2SC	1000(GR
					Q1202,1203,1205,1208	22318154	"	2SC	1815`	Y
		RESISTOR								
R1101,1112,1121	40143560	Carbon Film	¼W VJ							
R1102,1103,1108,1111	40143101	4 4	4 4	100Ω						
1118							DIODE			
R1119	40143221	4 4		220Ω	D1201~1210	21015550	Silicon	1S15	55	
R1105	40143821	" "		820Ω						
R1106,1122	40143102	<i>""</i>		1KΩ						
R1104	40143122	<i>* *</i>		1.2KΩ						
R1107 R1115	40143682	<i>""</i>		6.8KΩ			CRYSTAL	(100011	T	
	40143223	" "		22ΚΩ	X1201	71500174	110 207 0	(1800Hz 3.6864M)	12	
R1117	40143563	<i>" "</i>		56KΩ		71500188		(1750Hz 3.584MH		
R1109,1110,1120	40143104	<i>" "</i>		100KΩ		_	"	OPTION	(See	Table)
R1113,1114,1116	41143104	<i>" "</i>	<u> </u>	100KΩ						
· · · · · · · · · · · · · · · · · · ·										
		DOTENTION			VC1001		CRYSTAL SOC			
VR1101	10006500	POTENTIOMETER	5.4	TOKOD	XS1201	69010012	HC-25/U	SD01	.05	
***1101	49906503	EVL-SOAA 00B	04	50KΩB						
							DECICTOR			
		CAPACITOR			R1221	40142101	RESISTOR	1/117	171	1000
C1127	31820010		50WV CH	1PF	R1221 R1214	40143101	Carbon Film			100Ω
C1127	31820010			2PF	R1214 R1206	40143221		"	"	220Ω
C1128	31820020	······································		3PF		40143471		*	"	470Ω
C1113	31820030			10PF	R1212,1215,1222	40143102	<i>4 4</i>	"	"	1ΚΩ
C1112	31820100			10PF 22PF	1223,1225,1228	40140150				1 570
C1112 C1115	31820220 31829059				R1201	40143152	<u> </u>	*	"	1.5KΩ
C1102,1103	31829059 31829221	······		0.5PF	R1204	40143332	· · ·	<i>*</i>	"	3.3KΩ
C1114,1116,1120	31829221		* * 2	220PF	R1213	40143392	· · ·	*	"	3.9KΩ
C1109,1110	31827180	· · · ·			R1224	40143472	· · ·		"	4.7KΩ
C1101,1104~1107,1111	31827360	······································		36PF	R1202,1205,1209,1220	40143103	4 4	"	"	10KΩ
$1118,1119,1121 \sim 1125$	30020103	<i>y y</i>	<i>»</i> (0.01µF	1227,1229	411 (0100				10110
$1118,1119,1121 \sim 1125$	34220104	Flootnalutia	16WWT 1		R1229	41143103	* *	*		10KΩ
-1100,1120	34220106	Electrolytic	16WVT 1	10µ F	R1203	40143333	<i>"</i> "		VJ	33KΩ
					R1207,1218,1209 R1210,1211	40143104 40143274	11 11 11 11		4	100KΩ
								4	"	270KΩ

R1216,1217,1226	40143105	Carbon Film ¼W VJ 1M	ιΩ			RESISTOR				
				R1302	40143101	Carbon F	`ilm	1⁄4 W		100Ω
				R1310	40143151	"	"	"	"	150Ω
				R1307	40143471	*	"	"	"	470Ω
		POTENTIOMETER		R1308	40143222	"	*	"		2.2KΩ
VR1201~1204	49901103	EVL-S3AA 00B14 10H	KΩB	R1305	40143272	*	"	"	*	2.7KΩ
VR1205~1208,1210	49906103	EVL-SOAA 00B14 10H	KΩB	R1301	40143332	<i>"</i>	"	"	"	3.3KΩ
VR1209	49906205	EVL-S0AA 00B26 2M	IΩB	R1303	40143183	4	"	4	4	18KΩ
				R1304	40143333	"	4	"	~	33KΩ
				R1306,1309	40143104	"	4	4	"	100KΩ
		CAPACITOR								
C1228,1229	31829470	Ceramic Disc 50WV SL 471	PF							
C1201,1202,1205,1208	30820102		001µF			CAPACITOR				
1213,1216~1219				C1302	31820040	Ceramic	Disc	50W V	/ CH	4PF
$1220 \sim 1223$				C1304	31820330	"	4	4	"	33PF
C1214, 1215, 1227, 1234	30820103	<i>" " "</i> 0.(01µF	C1313	31820390	"	"	"	4	39PF
1235	00020100			C1305	31820510	*	4	<i>"</i>	"	51PF
C1224,1230~1232	36825103	Mylar % 0.0	01µF	C1311	31820680	*	"	4	4	68 PF
C1224,1230 1232	36825203		02µF	C1307,1310	31820221	"	"	"	"	220PF
C1236	36526334		33µ F	C1306	31820271	"	"	"		270PF
C1236	36526334		47μF	C1300	31827040		"	*	UJ	4PF
C1225,1226 C1203,1207,1211,1233		Electrolytic 50WV T 1µ		C1303	31827070	*	"		"	7PF
1237	34620105	Electrolytic John i Im		C1308,1309,1312	30820103	"	"	"		0.01µF
	34220106	∞ 16WVT 10/	μF	1314~1316	00020100	1				
C1210			μΓ μΓ	1514 1510	-					
C1204,1206,1212	34120476	7 10WV 1 4//	μ.1·	·	+					
						VARIABLE		TOP		
				37(3) 001	39000027	C521-112				
		RELAY		VC1301	39000027	0521-112				
RL1201	70000031	BR211A D012-M								
						TRIMMER (TUR		1505
		SWITCH		TC1301	39000070	TSN-100				15PF
S1201	63000012	ESD1426		TC1302	39000005	ECV-1Z	W 50×	32	•	50PF
								-		
				· · ·						
		MINI CONNECTOR				INDUCTOR				
J1201	68060013	MINI CONNECTOR 3022-06A		L1301	55003276					≢ 220314
J1201	68060013			L1301 L1302	53030001	Micro Ii			:	1mH
J1201	68060013					Micro Ii	nductor			
J1201	68060013			1.1302	53030001	Micro Ii				1mH
J1201	68060013			1.1302	53030001	Micro Ii			:	1mH
J1201	68060013	3022-06A		1.1302	53030001	Micro Ii				1mH
		3022-06A MINI PLUG		1.1302	53030001	Micro Ii	<i>*</i>			1mH
		3022-06A MINI PLUG		1.1302	53030001	Micro In	× 			1mH
		3022-06A MINI PLUG		I.1302 J.1303	53030001 53010001	Micro In CONNECTO	× 			1mH
		3022-06A MINI PLUG		I.1302 J.1303	53030001 53010001	Micro In CONNECTO	× 			1mH
P1201	67040006	3022-06A MINI PLUG 3021-04 with Jumper wire		I.1302 J.1303	53030001 53010001	Micro In CONNECTO	× 		:	1mH
P1201	67040006	3022-06A MINI PLUG 3021-04 with Jumper wire		I.1302 J.1303	53030001 53010001	Micro In CONNECTO	2	inal C		1mH
P1201	67040006	3022-06A MINI PLUG 3021-04 with Jumper wire		I.1302 J.1303	53030001 53010001 68040001	Micro In CONNECTO SI-6303	2	inal C		1mH
P1201	67040006	3022-06A MINI PLUG 3021-04 with Jumper wire		I.1302 J.1303	53030001 53010001 68040001	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201	67040006 91100008	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201	67040006 91100008	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 91100008	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201	67040006 91100008 91100008 Parts Number 60417740	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 Parts Number	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 91100008 Parts Number 60417740	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 91100008 Parts Number 60417740	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 91100008 Parts Number 60417740	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board 3380 VFO Unit assembly		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number PB-1774	67040006 91100008 91100008 V Rarts Rumber 60417740 017740 B7	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board 3380 VFO Unit assembly FET & TRANSISTOR		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH
P1201 TP1201 Symbol Number	67040006 91100008 91100008 Parts Number 60417740	3022-06A MINI PLUG 3021-04 with Jumper wire Wrapping terminal C FO UNIT Description Printed Circuit Board 3380 VFO Unit assembly		I.1302 J.1303	53030001 53010001 68040001 91100008	Micro In CONNECTOI SI-6303 Wrappir	≪ R g termi			1mH

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Symbol Mt		EG BOARD	R1501 1505	C 100010-	SWITCH
Symbol Number	Parts Number	Description	S1501,1505	64000101	SEL 62301
PB-1756 A	60417561	Printed Circuit Board	S1502,1503	64000103	SLE 62251
	017561AZ	P.C.B with components	S1504	64000108	SLE 64251
		IC & TRANSISTOR			
Q1404	25000116	IC μ PC14308S			
Q1402,1403	22303724	Transistor 2SC372Y		PUSH	SWITCH BOARD
Q1401	22402350	* 2SD313	Symbol Number	Parts Number	Description
			PB-1865	60418650	Printed Circuit Board
				018650A2	P.C.B with components
		DIODE			
D1401	21015550	DIODE Silicon 1S1555			· · · · · · · · · · · · · · · · · · ·
D1402	21013530	Zener WZ090	-		DIODE
			D1604,1606	21090011	Silicon 10D1
· · · · · · · · · · · · · · · · · · ·			D1601~1603.1605	-	
	-		1)1601~1603,1605	21090140	LED GD4-203-SRD
		PESISTOD			
R1401	40143331	RESISTOR Carbon Film ¼W VJ 330Ω			
R1401	40143331	$\frac{\text{Carbon Film}}{2} \frac{2}{3} \frac{2}{3} \frac{2}{3} \frac{1}{3} \frac{1}{3}$			RESISTOR
R1408	40143471 40143561		R1606	49194090	
R1402	40143561			42124220	Carbon Composition ½W GK 22
	-		R1604	42124221	
R1404	40143272	2,,,,,,,,,	R1601~1603	42124471	<u> </u>
R1406	44144059	Wire Wound ∞ 0.05Ω	R1605	42144563	<i>***</i> ** 5.6
	-	POTENTIOMETER			POTENTIOMETER
VR1401	49905471	$SR19R$ $470\Omega B$	VR1601	40006500	EVL-S0AA 00B54 50KΩI
	45505471	31(19) 47(041)		49906503	EVIL-SUAA 00054 - 50K141
	+	CAPACITOR			SWITCH
C1402	30820102	Ceramic Disc 50WV 0.001µ H	S1601~1604	65000036	MB-0202AA2060 B-2U-EE
C1404	34220476	Electrolytic 16VVT 47µF	S1605	65000037	MB-0201AA2060 B-2U-0A
C1403	34220227	* * 220μ F			
C1401	35320108	 25WV R 1000μ F 			
			-		
	91100008	Wrapping terminal C			CESSOR UNIT
			Symbol Number	Parts Number	Description
			PB-1866	60418660	Printed Circuit Board
				018660AZ	P.C.B with components
L	EVER S	WITCH BOARD			
Symbol Number	Parts Number	Description			IC, FET & TRANSISTOR
PB-1864	60418640	Printed Circuit Board	Q1711	25000105	IC TA7060P
	018640AZ	P.C.B with components	Q1703,1707	23800401	FET 3SK40M
		· · · · · · · · · · · · · · · · · · ·	Q1704,1705,1712	23800594	* 3SK59Y
		· · · · · · · · · · · · · · · · · · ·	Q1701,1702,1706	22318154	Transistor 2SC1815Y
		<u> </u>	1708~1710		
	1	DIODE		+	
			+	1	
	21010070	Germanium 1S1007			
)1501	21010070	Germanium 1S1007			
)1501	21010070	Germanium 1S1007			DIODE
)1501	21010070	Germanium 1S1007	D1701,1702	21010070	DIODE Germanium 1S1007
)1501	21010070	Germanium 1S1007 RESISTOR	D1701,1702 D1703~1706	21010070 21015550	· · · · · · · · · · · · · · · · · · ·
	21010070				Germanium 1S1007
21501		RESISTOR			Germanium 1S1007

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		CRYSTAL				ļ		TRANSFORMER		
X1701	71800127	HC-18/U 11.26	65MHz	#	210110	T1701,1702	54179430	R12-7943		
						T1703	54179470	R12-7947		
						T1704,1705	54140740	R12-4074	# 22	20150
						T1706,1707	54140730	R12-4073	# 22	0149
		CRYSTAL FILTE	R							
XF1701	71000036	XF10.8GA		#	210114					
· · · · · · · · · · · · · · · · · · ·										
						TP1701	91100008	Wrapping term	inal C	
		RESISTOR								
R1750, 1751, 1757, 1758		Carbon Film	1⁄4 W		56Ω					
R1710, 1716, 1723, 1737	40143101	11 11	"	"	·100Ω					
1739,1743,1744 R1714,1720	40143151	" "	"	"	150Ω		0.011			_
R1714, 1720 R1703, 1707, 1709	40143151			"	15012 220Ω	Symbol Number		NTER UNIT	· · · ·	
R1703,1707,1709	40143221	* *		"	470Ω	Symbol Number	Parts Number	Descr		
R1738,1742	40143471				470×2 560Ω	PB-1868	60418680	Printed Circui LED board		
R1728 R1701, 1715, 1721, 1733	40143301			"	1KΩ	PB-1867	60418680	Counter bo		
$1745 \sim 1748, 1756$	40145102	,	,	, in the second s	11/77	PB-1803	60418070			
R1738,1749,1752	40143222	<i>4 4</i>		"	2.2KΩ	1.0100	018670AZ	Connector Counter unit A		
R1705	40143222		*	"	4.7KΩ		010070AZ	Counter unit A	issembly	
R1703 R1711,1717,1724,1730	40143472	4 4	"		4.7Ka2 10KΩ					
1731,1735,1741										
R1722,1725,1755	40143223	" "	"	"	22KΩ			IC, FET & TRANS	SISTOR	
R1734, 1740, 1754	40143333	·/· ·/·	"		33KΩ	Q1807,1809	25000153	IC	F4011	
R1704,1708,1712,1713	40143473	4 4	"		47KΩ	Q1808	25000195	*	MC14069B	
1718,1719						Q1820	25000135		MSM561	
R1729	40143563	11 11	"	4	56KΩ	Q1805	25000054	"	MSM5564	
R1726,1753	40143104	<i>n n</i>	"	"	100KΩ	Q1821~1823	25000154	"	SN75453	<u> </u>
R1702,1732	40143184	" "	"	"	180KΩ	Q1802	25000104	"	SN76514	
R1727	40143224	4 4	4	"	220KΩ	Q1806	25000148	"	TC5032P	
R1706	40143474	" "	"	"	470KΩ	Q1801	22800195	FET	2SK19GR	
						Q1812	22104963	Transistor	2SA496(O)	
						Q1804,1810,1811	22303724	"	2SC372Y	
						Q1813~1819	2230496	*	2SC496	
		POTENTIOMETER				Q1803	22307842	"	2SC784R	
VR1702	49906102	EVL-SOAA 00	B13		1ΚΩΒ					-
VR1701	49906502	<u> </u>	B53		5ΚΩΒ					
			_							
								DISPLAY LED		
		CAPACITOR				DS1801~1806	21090135	5082-7740		
C1742	31829100	Ceramic Disc	50W V							
C1704	31829470	" "	"	· •	47PF					
C1719,1722_	31829560	<i>4 4</i>	"		56PF]					
C1701,1703,1708	31829101	<i>n n</i>	"	"	100PF			DIODE		
1728,1730,1732						D1804,1805	21001880	Germanium	1S188FM	
C1705,1706	31829151	<i>" "</i>	"		150PF	D1801,1802	21015550	Silicon	1S1555	
21720 1740	31829201	* *	"		200PF	D1803	21090011	"	10D1	
C1738,1743	30820102	· · ·			0.001µF	· · · · · · · · · · · · · · · · · · ·				
C1702,1707,1725,1729	30820103	11 11	"		0.01µF					
1731,1733~1737								00,000		
1739~1741,1744~1746						V1001				
1749,1750 C1709,1710	20200472	·····			0.047.5	X1801	71600033	HC-6/W 1.3107	72MHz #210	JU56
C1711,1715,1720	30820473 36825102				$0.047 \mu F$					
21711,1715,1720	36825102	Mylar %			$0.001 \mu F$					
21712,1716,1723 21713,1714,1717	36825103 36825473				$0.01 \mu F$			DESIGTOR		
1718,1726	30023413	<i>7</i> 7	"		0.047µF	D1942	40140470	RESISTOR	1/11/ 1/1	
21721	24820105	Fleaterlant		т	1 <i>4</i> F	R1843	40143470	Carbon Film	¹ ⁄ ₄ W VJ 470	
21721	34820105 34220106	Electrolytic	// // // // // // // // // // // // //		1μF	R1841	40143680	<i>"</i> , "	× × 680	
/1/64,1/6/	34220100	<i>"</i>	10 W V		10µ F	R1844	40143820	* *	<i>* *</i> 820	
						R1802~1804,1834	40143101	11 11	» « 100	121
						1835~1840,1842 R1807	40142001			
							40143221	" "	<u>* * 220</u>	
	1					R1811,1826	40143471	<i>4 4</i>	» × 470	102

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R1808	40143102	Carbon Film	<u>4W V</u>	/J 1ΚΩ			D BOARD
R1821	40143222	4 4	4	2.2KΩ	Symbol Number	Parts Number	Description
R1805	40143392	4 4	4	× 3.9KΩ	PB-1801	60418010	Printed Circuit Board
R1812,1813,1816,1818	40143103	4 4	4	 10KΩ 		018010AZ	P.C.B with components
1820,1825							
R1806,1809,1810	40143153	· · ·	"	15KΩ			
R1823	40143223	4 4	4	22KΩ			
R1814,1815,1817	40143563	4 4	4	» 56KΩ			DIODE
R1801,1822	40143104		4	 100KΩ 	D1901~1907	21090140	GD4-203SRD
R1824	40143105	<i></i>	~	× 1MΩ			
R1827~1833	42124330	Carbon Composi	ition ½W	GK 33Ω			
R1819	42144566	<i>"</i> "		GK 5.6MΩ			
							RESISTOR
					R1902~1905	42124331	Carbon Composition ¹ 2W GK 330Ω
					R1901	42124471	
		CAPACITOR					
C1822,1823	31820510	Ceramic Disc	50WV	CH 51PF			
C1806	31829010	<i>h h</i>	"	* 1PF			· · · · · · · · · · · · · · · · · · ·
C1805,1807	31829100	· · · ·	4	SL 10PF			
C1801	31829220	4 4	"	* 22PF	- <u> </u>		
C1825~1829,1832	31829221	4 4	~ ~ ~	* 220PF	C0	UNTER	BUFFER BOARD
C1808,1811,1838	30820102	<i>4 4</i>	4	0.001µF	Symbol Number	Parts Number	Description
1839~1842	30320102				PB-1671A-3380	60416711	Printed Circuit Board
C1802, 1804, 1809, 1810	30820103	· · ·		0.01µF	 -	016711BZ	P.C.B with components
$1812 \sim 1821, 1824$,		· · · · · · · · · · · · · · · · · · ·
1812 1821, 1824 1831, 1837, 1843, 1848							
C1833	36226224	Tantalum	35WV	0.22µF			
C1845~1847	32821102	Feed Thru	50WV	0.001µF			FET
C1830,1844	34220106	Electrolytic	16WV	10µ F	Q2001	22800195	2SK19GR
C1803	34120337	/	6.3WV	330µ F	Q2001	22000100	
C1836	34220477		16WV	470µ F			
C1849	35120108	······································	$-\frac{10WV}{10WV}$	1000µF			
01049	33120106		10.0.1	1000,41			RESISTOR
		han 14			R2002,2003	40143101	Carbon Film $\frac{1}{4}$ W VJ 100 Ω
			-		R2001	40143104	
······		MICRO INDUCTOR			12001	10110101	
L1801,1802	53020034	FL4H 100K	•	10µ H			
1.1001,1002	33020004			107.11		-	
							CAPACITOR
					C2001	31820470	Ceramic Disc 50WV CH 47PF
		TRANSFORMER			C2001	30820102	
T1801,1802				# 220408	02002,2003	30020102	
	55003293			# 220408			
Т1803	55003174			# 220209			
				<u></u>		· · · -	TRANSFORMER
				<u> </u>	120001		# 220209
1000.0					T2001	55003174	++ 220209
00	00000007	IC SOCKET		0010			
QS	68280001	116-28-30-114		2812			
QS	68140008	116-14-30-114		14P			
					Symbol Number	Parts Number_	Description
	91100008	Wrapping term	inal C		PB-1869	60418690	Printed Circuit Board
					PB-1804	60418041	Connector Board
						018690AZ	OSC unit with components
						+	
							TRANSISTOR
					Q2101,2102	22303730	Transistor 2SC373
					Q2103,2104	22307104	/ 2SC710D
						1	
						· · · · · · · · · · · · · · · · · · ·	
					1		
							· · · · · · · · · · · · · · · · · · ·

		DIODE			RKER UNIT
D2101~2104	21015550	Silcon 1S1555	Symbol Number	Parts Number	Description
D2105~2108	21090142	« МС301	PB-1802	60418020	Printed Circuit Board
			PB-1804	60418040	Connector Board B
				018020BZ	Marker unit with components
· . <u>-</u>					
······		CRYSTAL	t		
X2101	71800128	HC-18/U 14.20269MHz #210118-1			
X2102	71800129	/ 14.20223MHz #210118-2			IC & TRANSISTOR
<u> </u>	71800129		()2203	25000108	IC 34024PC
			Q2201,2202,2204	22303724	Transistor 2SC372Y
			(2201,2202,2204	22000121	
		RESISTOR			
R2115,2119	41143101	Carbon Film $\frac{1}{4}$ W VJ 100 Ω			
R2120	41143221				DIODE
R2116	41143561		1)0001	01000100	
R2101~2106,2109	41143102	» » » « 1KΩ	D2201	21090139	Zener RD8.2EB
2112	<u> </u>				
R2118	41143222	<u>* * * 2.2KΩ</u>			
R2114	41143472	~ ~ ~ ~ 4.7KΩ			
R2108,2111,2117	41143103	~ ~ ~ ~ 10KΩ	· · · · · · · · · · · · · · · · · · ·		CRYSTAL
R2107,2110,2113	41143223	« « « « 22KΩ	X2201	71800060	HC-18/U 12.8MHz
		CAPACITOR			RESISTOR
C2109~2112	31820470	Ceramic Disc 50WV CH 47PF	R2209	40143271	Carbon Film ¼W VJ 270Ω
C2123,2130	31829010	* * * SL 1PF	R2203,2205	40143102	· · · · · · ΙΚΩ
C2129	31829090	// / / / / / / / / / / / / / / / / / /	R2208	40143222	« « « « 2.2KΩ
C2116,2120,2131	31829100	* * * * 10PF	R2202	40143103	« « « 10KΩ
C2134	31829120	// // // // 12PF	R2201,2207	40143223	<i>~ ~ ~ ~ ~ ~ ~ 22KΩ</i>
C2134	31829390	* * * * 39 PF	R2206	40143104	· · · · · 100KΩ
	31829390	// // // // // // // // // // // // //	112200	40143224	* * * * 220KΩ
C2124			· · · · · · · · · · · · · · · · · · ·	40145224	220101
C2132	31829820				
C2125	31829151	* * * 150PF			
C2105~2108,2113	30820103	<i>« « α</i> 0.01μF			· · · · · · · · · · · · · · · · · · ·
2117,2121,2126~2128					
2133					CAPACITOR
C2115,2119	36824101	Styrol / 100PF	C2201,2207	31820272	Ceramic Disc 50WV CH 27PF
C2114,2118	36824221	* * 220PF	C2202,2203	31820221	* * * * 220PF
C2135~2139	32821102	Feed Thru 🧳 0.001µF	C2208	31829030	* * * SL 3PF
C2101~2104	34220106	Electrolytic 16WV T 10µF	C2204~2206,2210	30820103	<i>* * *</i> 0.01μ F
		·····	C2209	35220106	Electrolytic 16WV T 10µF
···					
			1		
		TRIMMER CAPACITOR	† · · · · -		TRIMMER CAPACITOR
TC2101~2104	39000008	ECV-1ZW 40×40 40PF	TC2201	39000007	ECV-1ZW 20×40 20PF
102101 2101	3300000				
		· · · · · · · · · · · · · · · · · · ·	†	+	
	+			1	
		MICRO INDUCTOR			
L2101~2106	53020001	FL-5H 102K 1mH		1	MICRO INDUCTOR
	00020001		L2201	53010002	22µH
<u> </u>			L2202	53010002	250µH
			1.6606	33010003	230µ 11
		TRANSFORMER		-	
			l		
T2101~2104	55003319	IFT # 220347			
					MINI CONNECTOR
			J2201	67130001	5048-13A
	91100008	Wrapping terminal C			
			ТР	91100008	Wrapping terminal C
		MINI CONNECTOR			
	67130001	5048-13A	1		

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		ONTROL UNIT		AC	ESSORIES
Symbol Number	Parts Number	Description	Symbol Number	Parts Number	Description
PB-1898	60418980	Printed Board Circuit		77000011	Microphone Assembly YE-11
	018980AZ	P.C.B with components			with Microphone hanger, Screws
		· · · · · · · · · · · · · · · · · · ·		67040001	Microphone Plug FM-144P
			· · · · · · · · · · · · · · · · · · ·	67020005	
				67050003	Accessory plug CP-008
		TRANSISTOR		67020002	Key plug SH3001
Q2301,2302	22318154	2SC1815Y		67020003	External Speaker, Headphone
		<u> </u>			plug P-2240
				6700000	
				67030002	Plug Adaptor KA409
				67020001	Pin plug CN7017
		1.000 V 1/1.0000		73000003	Fuse 3A (AC100-117V)
		RESISTOR		73000002	Fuse 2A (AC200-234V)
D0004	40140159				Fuse 10A (DC)
R2304	40143152	Carbon Film ¼W VJ 1.5KΩ		73000005	
R2303	40143103	» « « 10KΩ		96000001	AC Power Cord #24001
R2301	40143473	» » » » 47KΩ		68040005	Power Plug QMS-F
R2302	40143154	γ γ γ γ 150KΩ		96000035	DC Power Cord #24006
_ • • •				68040005	Power plug QMS-P
:	· · · ·			69030002	Fuse Holder SN SN1101
·					
		· · · · · · · · · · · · · · · · · · ·			
		POTENTIOMETER		+ -	
VR2301	49901503	EVL-S3A 00B54 50KΩB			
		· · · · · · · · · · · · · · · · · · ·			
		CAPACITOR			
C2301~2305	30820103	Ceramic Disc 50WV 0.01µF	· ··= ·		
2301 2303	00020100				
				T	
	+ -		- · · · · · · · · · · · · · · · · · · ·		
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